

## Operational Amplifiers Series

# Ground Sense

# High Speed Low Voltage CMOS Operational Amplifiers

**BU7485G BU7485SG BU7486xxx BU7486Sxxx BU7487xx BU7487Sxx**

## General Description

BU7485G/BU7486xxx/BU7487xx are CMOS operational amplifiers with input ground sense and full swing output. This series has extended operational amplifiers BU7485SG/BU7486Sxxx/BU7487Sxx which can operate over a wider temperature range (-40°C to +105°C). These ICs have wide band, high slew rate, low voltage operation and low input bias current, making the operational amplifiers suitable for portable equipment and sensor application.

## Features

- High Slew Rate
- Wide Bandwidth
- Low Input Bias Current
- Output Full Swing

## Application

- Battery-powered Equipment
- General Purpose Electronics

## Key Specifications

- Operating Power Supply Voltage Range (Single Supply): +3.0V to +5.5V
- Slew Rate: 10.0V/μs
- Temperature Range:
  - BU7485G -40°C to +85°C
  - BU7486xxx -40°C to +85°C
  - BU7487xx -40°C to +85°C
  - BU7485S -40°C to +105°C
  - BU7486Sxxx -40°C to +105°C
  - BU7487Sxx -40°C to +105°C
- Input Bias Current: 1pA (Typ)
- Input Offset Current: 1pA (Typ)

## Package

	W(Typ) x D(Typ) x H(Max)
SSOP5	2.90mm x 2.80mm x 1.25mm
SOP8	5.00mm x 6.20mm x 1.71mm
SSOP-B8	3.00mm x 6.40mm x 1.35mm
MSOP8	2.90mm x 4.00mm x 0.90mm
SOP14	8.70mm x 6.20mm x 1.71mm
SSOP-B14	5.00mm x 6.40mm x 1.35mm

## Simplified schematic

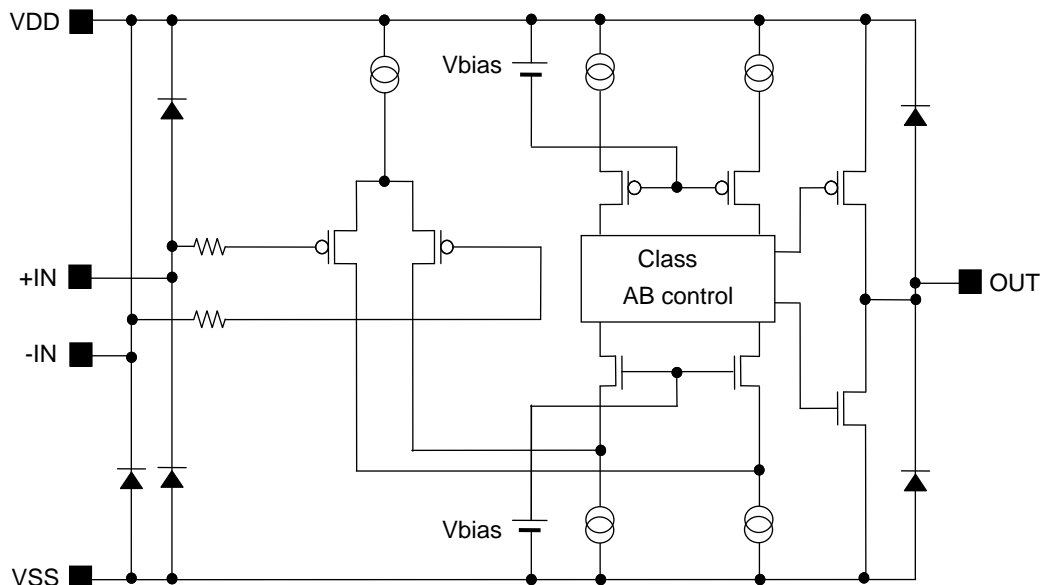
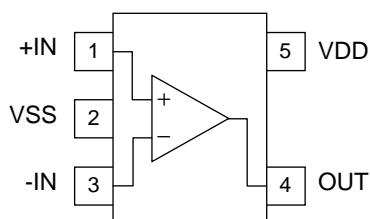


Figure 1. Simplified schematic (1 channel only)

○Product structure : Silicon monolithic integrated circuit ○This product is not designed protection against radioactive rays.

## Pin Configuration

BU7485G, BU7485SG : SSOP5

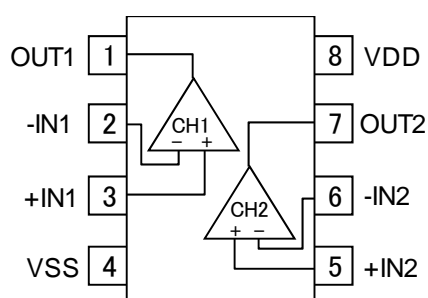


Pin No.	Pin Name
1	+IN
2	VSS
3	-IN
4	OUT
5	VDD

BU7486F, BU7486SF : SOP8

BU7486FV, BU7486SFV : SSOP-B8

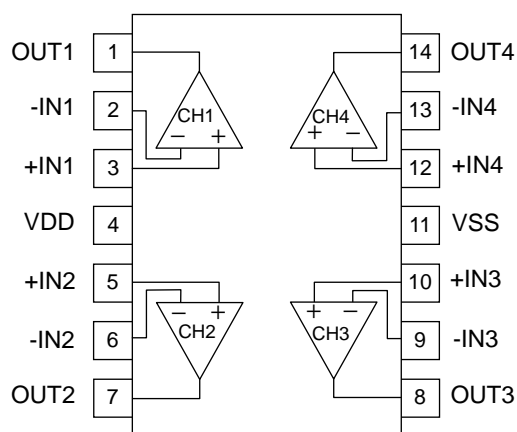
BU7486FVM, BU7486SFVM : MSOP8



Pin No.	Pin Name
1	OUT1
2	-IN1
3	+IN1
4	VSS
5	+IN2
6	-IN2
7	OUT2
8	VDD

BU7487F, BU7487SF : SOP14

BU7487FV, BU7487SFV : SSOP-B14



Pin No.	Pin Name
1	OUT1
2	-IN1
3	+IN1
4	VDD
5	+IN2
6	-IN2
7	OUT2
8	OUT3
9	-IN3
10	+IN3
11	VSS
12	+IN4
13	-IN4
14	OUT4

Package					
SSOP5	SOP8	SSOP-B8	MSOP8	SOP14	SSOP-B14
BU7485G BU7485SG	BU7486F BU7486SF	BU7486FV BU7486SFV	BU7486FVM BU7486SFVM	BU7487F BU7487SF	BU7487FV BU7487SFV

## Ordering Information

B U 7 4 8 x x x x x

- X X

## Part Number

BU7485G  
 BU7485SG  
 BU7486xxx  
 BU7486Sxxx  
 BU7487xx  
 BU7487Sxx

## Package

G: SSOP5  
 F: SOP8  
 SOP14  
 FV: SSOP-B8  
 SSOP-B14  
 FVM: MSOP8

## Packaging and forming specification

E2: Embossed tape and reel  
 (SOP8/SSOP-B8/SOP14/ SSOP-B14)  
 TR: Embossed tape and reel  
 (SSOP5/MSOP8)

## Line-up

Topr	Package		Operable Part Number
-40°C to +85°C	SSOP5	Reel of 3000	BU7485G-TR
	SOP8	Reel of 2500	BU7486F-E2
	SSOP-B8	Reel of 2500	BU7486FV-E2
	MSOP8	Reel of 3000	BU7486FVM-TR
	SOP14	Reel of 2500	BU7487F-E2
	SSOP-B14	Reel of 2500	BU7487FV-E2
-40°C to +105°C	SSOP5	Reel of 3000	BU7485SG-TR
	SOP8	Reel of 2500	BU7486SF-E2
	SSOP-B8	Reel of 2500	BU7486SFV-E2
	MSOP8	Reel of 3000	BU7486SFVM-TR
	SOP14	Reel of 2500	BU7487SF-E2
	SSOP-B14	Reel of 2500	BU7487SFV-E2

## Absolute Maximum Ratings(Ta=25°C)

Parameter	Symbol	Ratings		Unit
		BU7485G/BU7486xxx /BU7487xx	BU7485Sx/BU7486Sxxx /BU7487Sxx	
Supply Voltage	VDD-VSS	+7		V
Power dissipation	Pd	SSOP5	0.54 <sup>*1,7</sup>	W
		SOP8	0.55 <sup>*2,7</sup>	
		SSOP-B8	0.50 <sup>*3,7</sup>	
		MSOP8	0.47 <sup>*4,7</sup>	
		SOP14	0.70 <sup>*5,7</sup>	
		SSOP-B14	0.45 <sup>*6,7</sup>	
Differential Input Voltage <sup>*8</sup>	Vid	VDD – VSS		V
Input Common-mode Voltage Range	Vicm	(VSS - 0.3) to VDD + 0.3		V
Input Current <sup>*9</sup>	Ii	±10		mA
Operating Supply Voltage	Vopr	+3.0 to +5.5		V
Operating Temperature	Topr	-40 to +85	-40 to +105	°C
Storage Temperature	Tstg	-55 to +125		°C
Maximum Junction Temperature	Tjmax	+125		°C

Note: Absolute maximum rating item indicates the condition which must not be exceeded.

Application of voltage in excess of absolute maximum rating or use out absolute maximum rated temperature environment may cause deterioration of characteristics.

\*1 To use at temperature above Ta=25°C reduce 5.4mW.

\*2 To use at temperature above Ta=25°C reduce 5.5mW.

\*3 To use at temperature above Ta=25°C reduce 5.0mW.

\*4 To use at temperature above Ta=25°C reduce 4.7mW.

\*5 To use at temperature above Ta=25°C reduce 7.0mW.

\*6 To use at temperature above Ta=25°C reduce 4.5mW.

\*7 Mounted on a FR4 glass epoxy PCB(70mm×70mm×1.6mm).

\*8 The voltage difference between inverting input and non-inverting input is the differential input voltage. Then input pin voltage is set to more than VSS.

\*9 An excessive input current will flow when input voltages of more than VDD+0.6V or lesser than VSS-0.6V are applied. The input current can be set to less than the rated current by adding a limiting resistor.

**Electrical Characteristics**

OBU7485G, BU7485SG (Unless otherwise specified VDD=+3V, VSS=0V, Ta=25°C)

Parameter	Symbol	Temperature Range	Limits			Unit	Condition
			Min	Typ	Max		
Input Offset Voltage <sup>*10</sup>	Vio	25°C	-	1	9.5	mV	-
Input Offset Current <sup>*10</sup>	Iio	25°C	-	1	-	pA	-
Input Bias Current <sup>*10</sup>	Ib	25°C	-	1	-	pA	-
Supply Current <sup>*11</sup>	IDD	25°C	-	1500	2000	μA	RL=∞ Av=0dB, IN=0.8V
		Full range	-	-	2400		
Maximum Output Voltage (High)	VOH	25°C	VDD-0.1	-	-	V	RL=10kΩ
Maximum Output Voltage (Low)	VOL	25°C	-	-	VSS+0.1	V	RL=10kΩ
Large Signal Voltage Gain	Av	25°C	70	105	-	dB	RL=10kΩ
Input Common-mode Voltage Range	Vicm	25°C	0	-	1.6	V	VSS to VDD-1.4V
Common-mode Rejection Ratio	CMRR	25°C	45	60	-	dB	-
Power Supply Rejection Ratio	PSRR	25°C	60	80	-	dB	-
Output Source Current <sup>*12</sup>	Isource	25°C	4	8	-	mA	VDD-0.4V
Output Sink Current <sup>*12</sup>	Isink	25°C	7	12	-	mA	VSS+0.4V
Slew Rate	SR	25°C	-	10	-	V/μs	CL=25pF
Unity Gain Frequency	f <sub>T</sub>	25°C	-	10	-	MHz	CL=25pF, Av=40dB
Phase Margin	θ	25°C	-	50	-	deg	CL=25pF, Av=40dB
Total Harmonic Distortion +Noise	THD+N	25°C	-	0.03	-	%	OUT=0.7V <sub>P-P</sub> , f=1kHz

<sup>\*10</sup> Absolute value<sup>\*11</sup> Full range BU7485G: Ta=-40°C to +85°C BU7485SG: Ta=-40°C to +105°C<sup>\*12</sup> Under the high temperature environment, consider the power dissipation of IC when selecting the output current.  
When the terminal short circuits are continuously output, the output current is reduced to climb to the temperature inside IC.

OBU7486xxx, BU7486Sxxx (Unless otherwise specified VDD=+3V, VSS=0V, Ta=25°C)

Parameter	Symbol	Temperature Range	Limits			Unit	Condition
			Min	Typ	Max		
Input Offset Voltage <sup>*13</sup>	Vio	25°C	-	1	9.5	mV	-
Input Offset Current <sup>*13</sup>	Iio	25°C	-	1	-	pA	-
Input Bias Current <sup>*13</sup>	Ib	25°C	-	1	-	pA	-
Supply Current <sup>*14</sup>	IDD	25°C	-	3000	4000	μA	RL=∞, All Op-Amps Av=0dB, IN=0.8V
		Full range	-	-	4500		
Maximum Output Voltage (High)	VOH	25°C	VDD-0.1	-	-	V	RL=10kΩ
Maximum Output Voltage (Low)	VOL	25°C	-	-	VSS+0.1	V	RL=10kΩ
Large Signal Voltage Gain	Av	25°C	70	105	-	dB	RL=10kΩ
Input Common-mode Voltage Range	Vicm	25°C	0	-	1.6	V	VSS to VDD-1.4V
Common-mode Rejection Ratio	CMRR	25°C	45	60	-	dB	-
Power Supply Rejection Ratio	PSRR	25°C	60	80	-	dB	-
Output Source Current <sup>*15</sup>	Isource	25°C	4	8	-	mA	VDD-0.4V
Output Sink Current <sup>*15</sup>	Isink	25°C	7	12	-	mA	VSS+0.4V
Slew Rate	SR	25°C	-	10	-	V/μs	CL=25pF
Unity Gain Frequency	fT	25°C	-	10	-	MHz	CL=25pF, Av=40dB
Phase Margin	θ	25°C	-	50	-	deg	CL=25pF, Av=40dB
Total Harmonic Distortion +Noise	THD+N	25°C	-	0.03	-	%	OUT=0.7Vp-p, f=1kHz
Channel Separation	CS	25°C	-	100	-	dB	Av=40dB

<sup>\*13</sup> Absolute value

<sup>\*14</sup> Full range BU7486xxx: Ta=-40°C to +85°C BU7486Sxxx: Ta=-40°C to +105°C

<sup>\*15</sup> Under the high temperature environment, consider the power dissipation of IC when selecting the output current.

When the terminal short circuits are continuously output, the output current is reduced to climb to the temperature inside IC.

OBU7487xx, BU7487Sxx (Unless otherwise specified VDD=+3V, VSS=0V, Ta=25°C)

Parameter	Symbol	Temperature Range	Limits			Unit	Condition
			Min	Typ	Max		
Input Offset Voltage <sup>*16</sup>	Vio	25°C	-	1	9.5	mV	-
Input Offset Current <sup>*16</sup>	Iio	25°C	-	1	-	pA	-
Input Bias Current <sup>*16</sup>	Ib	25°C	-	1	-	pA	-
Supply Current <sup>*17</sup>	IDD	25°C	-	6000	8000	μA	RL=∞, All Op-Amps Av=0dB, IN=0.8V
		Full range	-	-	9000		
Maximum Output Voltage (High)	VOH	25°C	VDD-0.1	-	-	V	RL=10kΩ
Maximum Output Voltage (Low)	VOL	25°C	-	-	VSS+0.1	V	RL=10kΩ
Large Signal Voltage Gain	Av	25°C	70	105	-	dB	RL=10kΩ
Input Common-mode Voltage Range	Vicm	25°C	0	-	1.6	V	VSS to VDD-1.4V
Common-mode Rejection Ratio	CMRR	25°C	45	60	-	dB	-
Power Supply Rejection Ratio	PSRR	25°C	60	80	-	dB	-
Output Source Current <sup>*18</sup>	Isource	25°C	4	8	-	mA	VDD-0.4V
Output Sink Current <sup>*18</sup>	Isink	25°C	7	12	-	mA	VSS+0.4V
Slew Rate	SR	25°C	-	10	-	V/μs	CL=25pF
Unity Gain Frequency	fT	25°C	-	10	-	MHz	CL=25pF, Av=40dB
Phase Margin	θ	25°C	-	50	-	deg	CL=25pF, Av=40dB
Total Harmonic Distortion +Noise	THD+N	25°C	-	0.03	-	%	OUT=0.7Vp-p, f=1kHz
Channel Separation	CS	25°C	-	100	-	dB	Av=40dB

<sup>\*16</sup> Absolute value

<sup>\*17</sup> Full range BU7487xx: Ta=-40°C to +85°C BU7487Sxx: Ta=-40°C to +105°C

<sup>\*18</sup> Under the high temperature environment, consider the power dissipation of IC when selecting the output current.

When the terminal short circuits are continuously output, the output current is reduced to climb to the temperature inside IC.

## Description of Electrical Characteristics

Described below are descriptions of the relevant electrical terms used in this datasheet. Items and symbols used are also shown. Note that item name and symbol and their meaning may differ from those on another manufacturer's document or general document.

### 1. Absolute maximum ratings

Absolute maximum rating items indicate the condition which must not be exceeded. Application of voltage in excess of absolute maximum rating or use out of absolute maximum rated temperature environment may cause deterioration of characteristics.

#### 1.1 Supply Voltage (VDD/VSS)

Indicates the maximum voltage that can be applied between the VDD terminal and VSS terminal without deterioration or destruction of characteristics of internal circuit.

#### 1.2 Differential Input Voltage (Vid)

Indicates the maximum voltage that can be applied between non-inverting and inverting terminals without damaging the IC.

#### 1.3 Input Common-mode Voltage Range (Vicm)

Indicates the maximum voltage that can be applied to the non-inverting and inverting terminals without deterioration or destruction of electrical characteristics. Input common-mode voltage range of the maximum ratings does not assure normal operation of IC. For normal operation, use the IC within the input common-mode voltage range characteristics.

#### 1.4 Power dissipation (Pd)

Indicates the power that can be consumed by the IC when mounted on a specific board at the ambient temperature 25°C (normal temperature). As for package product, Pd is determined by the temperature that can be permitted by the IC in the package (maximum junction temperature) and the thermal resistance of the package.

### 2. Electrical characteristics

#### 2.1 Input Offset Voltage (Vio)

Indicates the voltage difference between non-inverting terminal and inverting terminals. It can be translated into the input voltage difference required for setting the output voltage at 0 V.

#### 2.2 Input Offset Current (Iio)

Indicates the difference of input bias current between the non-inverting and inverting terminals.

#### 2.3 Input Bias Current (Ib)

Indicates the current that flows into or out of the input terminal. It is defined by the average of input bias currents at the non-inverting and inverting terminals.

#### 2.4 Supply Current (IDD)

Indicates the current that flows within the IC under specified no-load conditions.

#### 2.5 Maximum Output Voltage(High) / Maximum Output Voltage(Low) (VOH/VOL)

Indicates the voltage range of the output under specified load condition. It is typically divided into maximum output voltage High and low. Maximum output voltage high indicates the upper limit of output voltage. Maximum output voltage low indicates the lower limit.

#### 2.6 Large Signal Voltage Gain (Av)

Indicates the amplifying rate (gain) of output voltage against the voltage difference between non-inverting terminal and inverting terminal. It is normally the amplifying rate (gain) with reference to DC voltage.

$$A_v = (\text{Output voltage}) / (\text{Differential Input voltage})$$

#### 2.7 Input Common-mode Voltage Range (Vicm)

Indicates the input voltage range where IC normally operates.

#### 2.8 Common-mode Rejection Ratio (CMRR)

Indicates the ratio of fluctuation of input offset voltage when the input common mode voltage is changed. It is normally the fluctuation of DC.

$$CMRR = (\text{Change of Input common-mode voltage}) / (\text{Input offset fluctuation})$$

#### 2.9 Power Supply Rejection Ratio (PSRR)

Indicates the ratio of fluctuation of input offset voltage when supply voltage is changed.

It is normally the fluctuation of DC.

$$PSRR = (\text{Change of power supply voltage}) / (\text{Input offset fluctuation})$$

#### 2.10 Output Source Current/ Output Sink Current (Isource / Isink)

The maximum current that can be output from the IC under specific output conditions. The output source current indicates the current flowing out from the IC, and the output sink current indicates the current flowing into the IC.

#### 2.11 Slew Rate (SR)

Indicates the ratio of the change in output voltage with time when a step input signal is applied.

#### 2.12 Unity Gain Frequency (f<sub>T</sub>)

Indicates a frequency where the voltage gain of operational amplifier is 1.

#### 2.13 Phase Margin (θ)

Indicates the margin of phase from 180 degree phase lag at unity gain frequency.

#### 2.14 Total Harmonic Distortion+Noise (THD+N)

Indicates the fluctuation of input offset voltage or that of output voltage with reference to the change of output voltage of driven channel.

#### 2.15 Channel Separation (CS)

Indicates the fluctuation in the output voltage of the driven channel with reference to the change of output voltage of the channel which is not driven.

# Typical Performance Curves

OBU7485G, BU7485SG

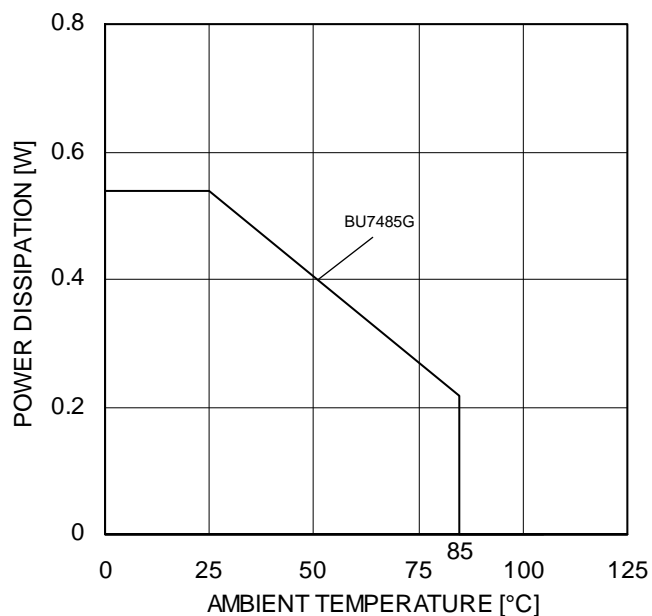


Figure 2.  
Derating curve

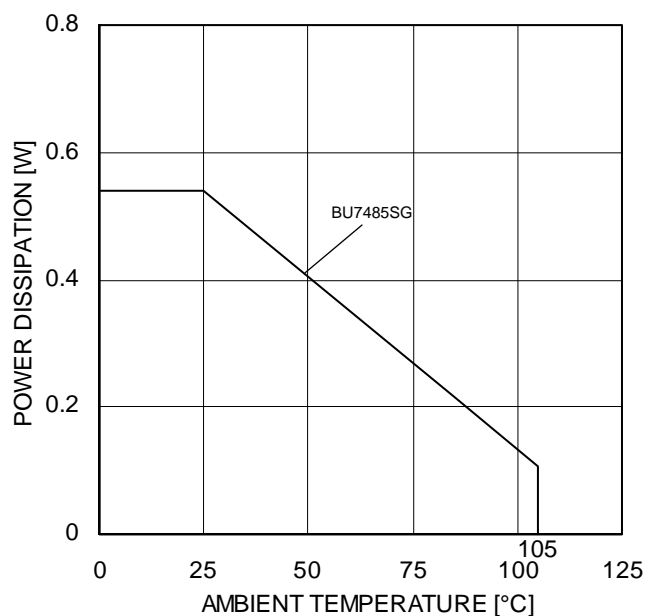


Figure 3.  
Derating curve

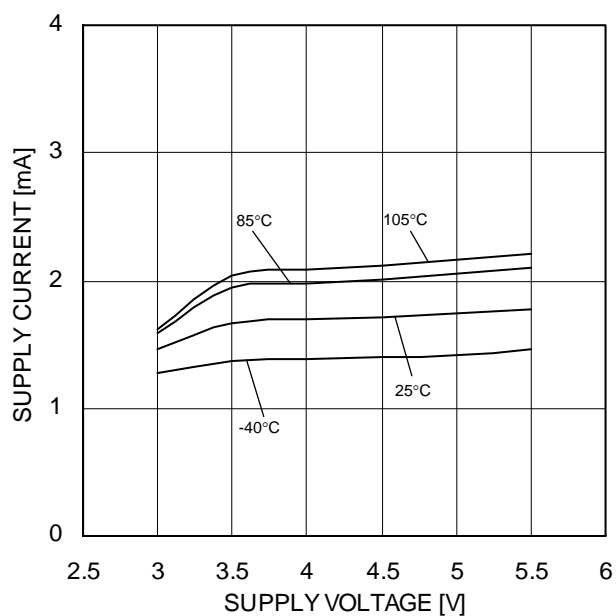


Figure 4.  
Supply Current – Supply Voltage

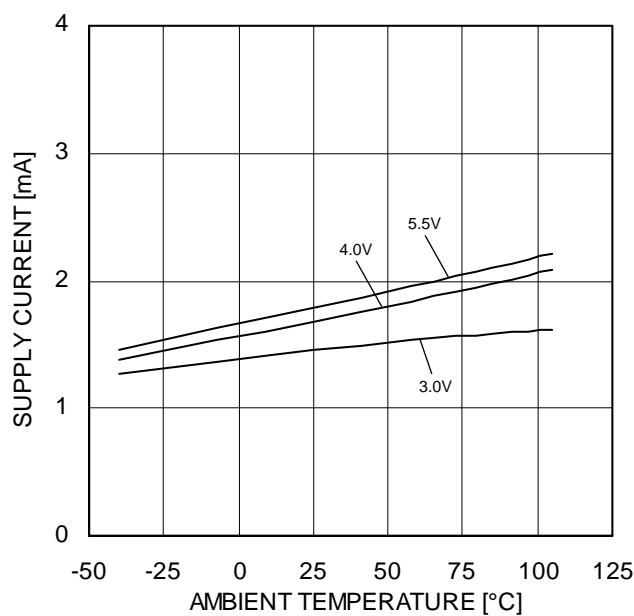


Figure 5.  
Supply Current – Ambient Temperature

(\*)The above characteristics are measurements of typical sample, they are not guaranteed.

BU7485G: -40°C to +85°C BU7485SG: -40°C to +105°C



# Typical Performance Curves - Continued

OB7485G, BU7485SG

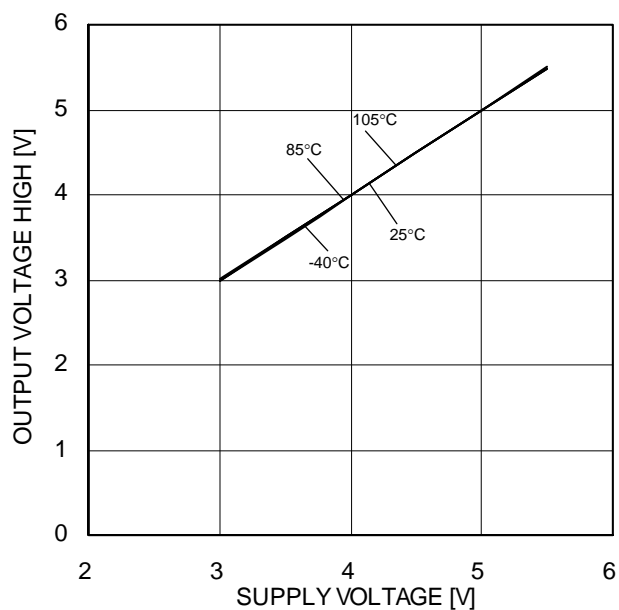


Figure 6.  
Maximum Output Voltage High –  
Supply Voltage  
( $R_L=10k\Omega$ )

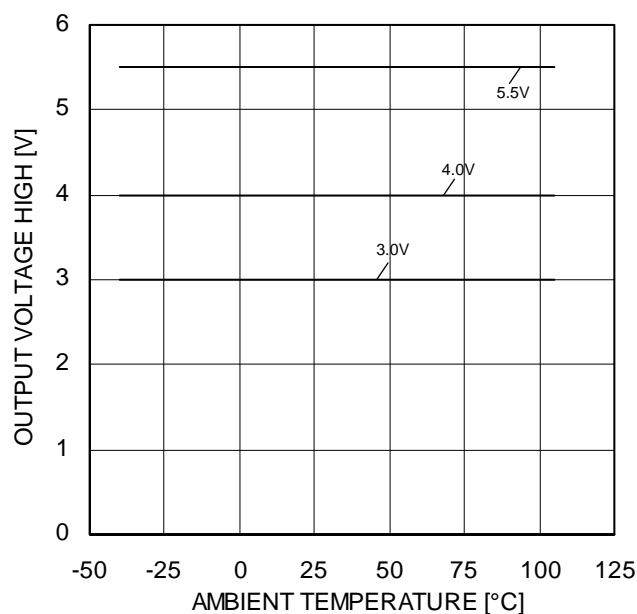


Figure 7.  
Maximum Output Voltage High –  
Ambient Temperature  
( $R_L=10k\Omega$ )

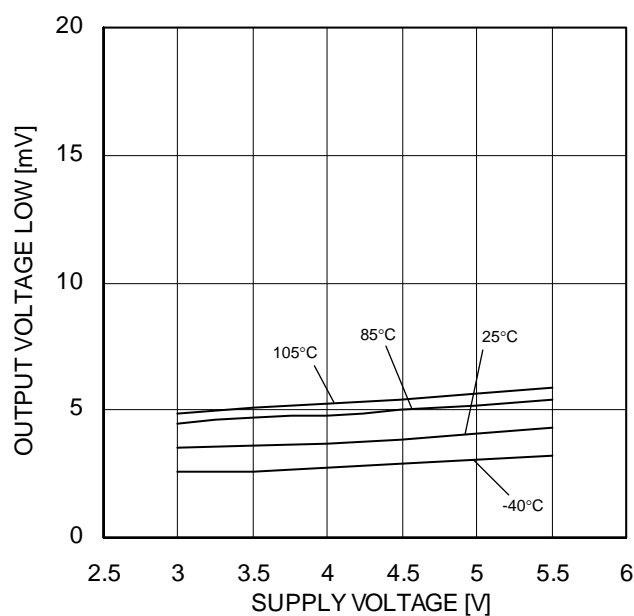


Figure 8.  
Maximum Output Voltage Low –  
Supply Voltage  
( $R_L=10k\Omega$ )

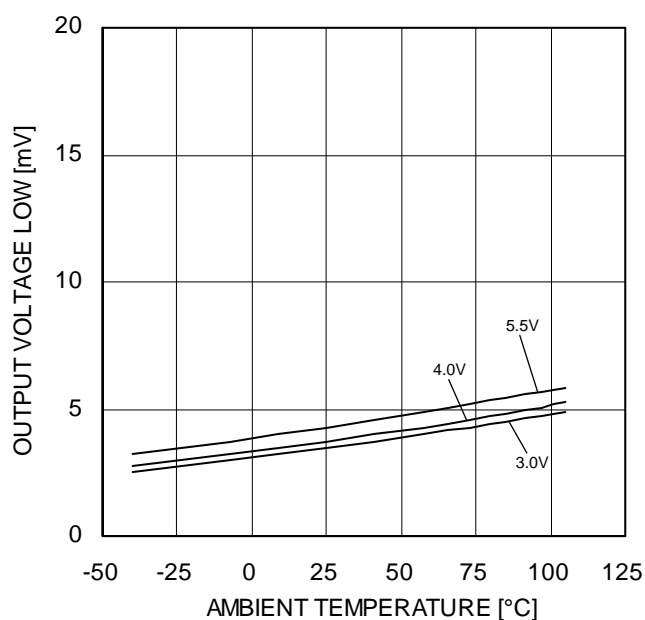


Figure 9.  
Maximum Output Voltage Low –  
Ambient Temperature  
( $R_L=10k\Omega$ )

(\*)The above characteristics are measurements of typical sample, they are not guaranteed.

BU7485G: -40°C to +85°C BU7485SG: -40°C to +105°C

# Typical Performance Curves - Continued

OBU7485G, BU7485SG

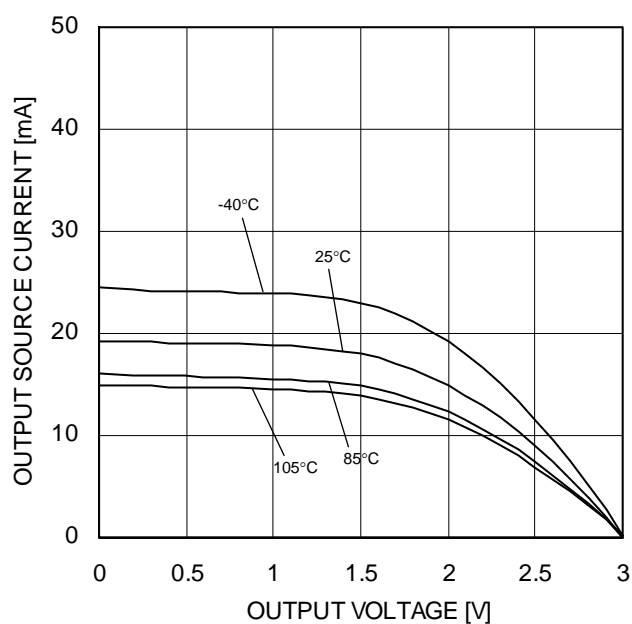


Figure 10.  
Output Source Current – Output Voltage  
(VDD=3V)

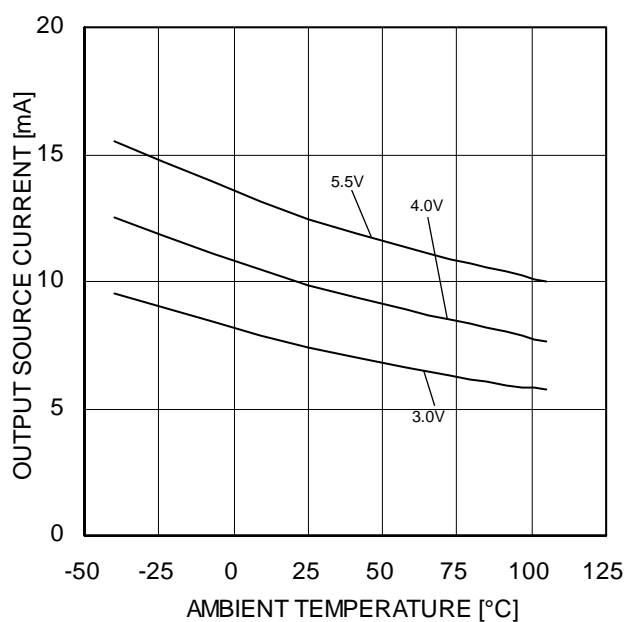


Figure 11.  
Output Source Current – Ambient Temperature  
(OUT=VDD-0.4V)

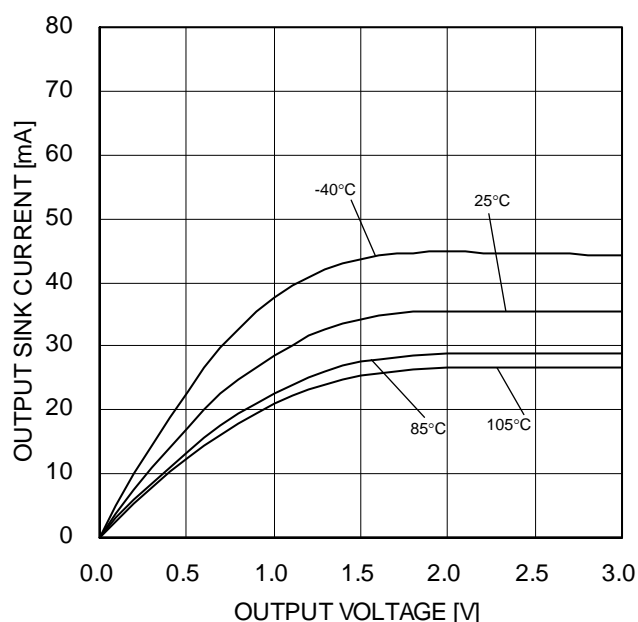


Figure 12.  
Output Sink Current – Output Voltage  
(VDD=3V)

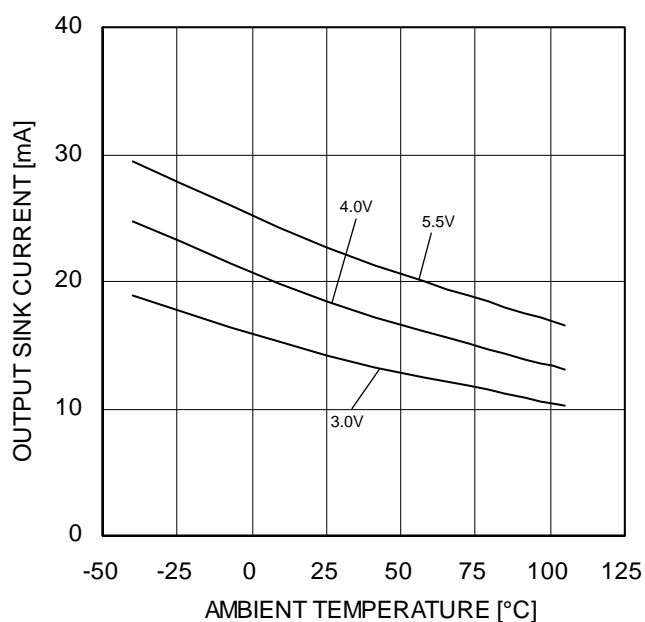


Figure 13.  
Output Sink Current – Ambient Temperature  
(OUT=VSS+0.4V)

(\*)The above characteristics are measurements of typical sample, they are not guaranteed.

BU7485G: -40°C to +85°C BU7485SG: -40°C to +105°C

# Typical Performance Curves - Continued

OBU7485G, BU7485SG

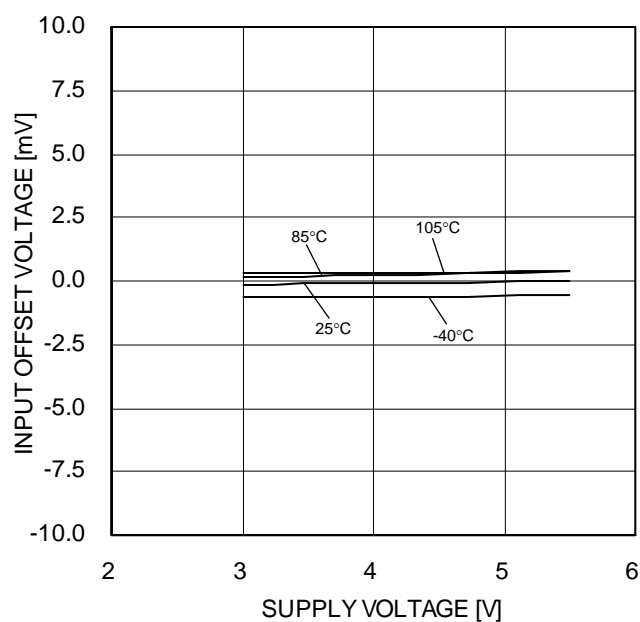


Figure 14.  
Input Offset Voltage – Supply Voltage  
( $V_{icm}=V_{DD}-1.4V$ ,  $OUT=1.5V$ )

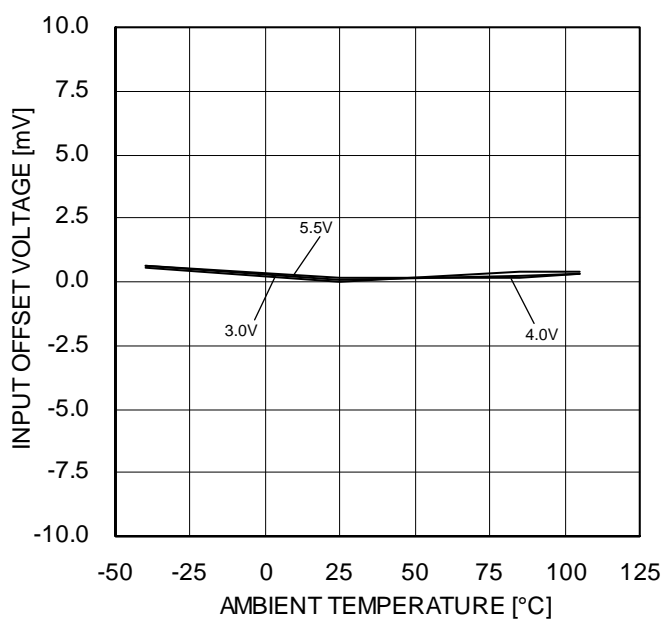


Figure 15.  
Input Offset Voltage – Ambient Temperature  
( $V_{icm}=V_{DD}-1.4V$ ,  $OUT=1.5V$ )

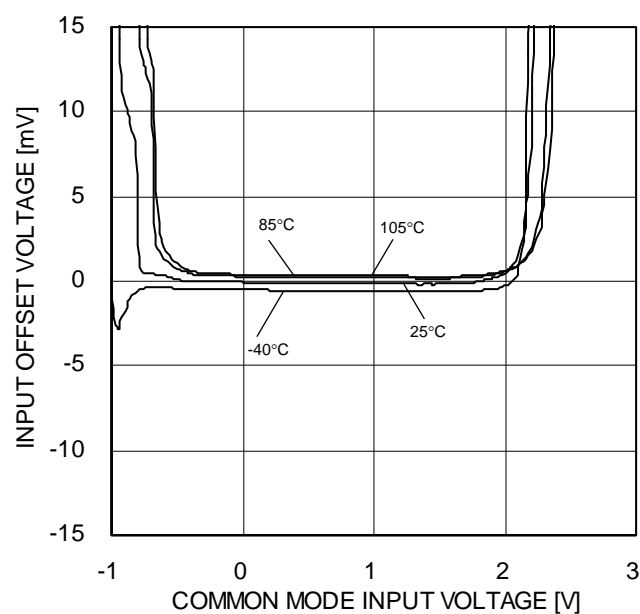


Figure 16.  
Input Offset Voltage – Common Mode  
Input Voltage  
( $V_{DD}=3V$ )

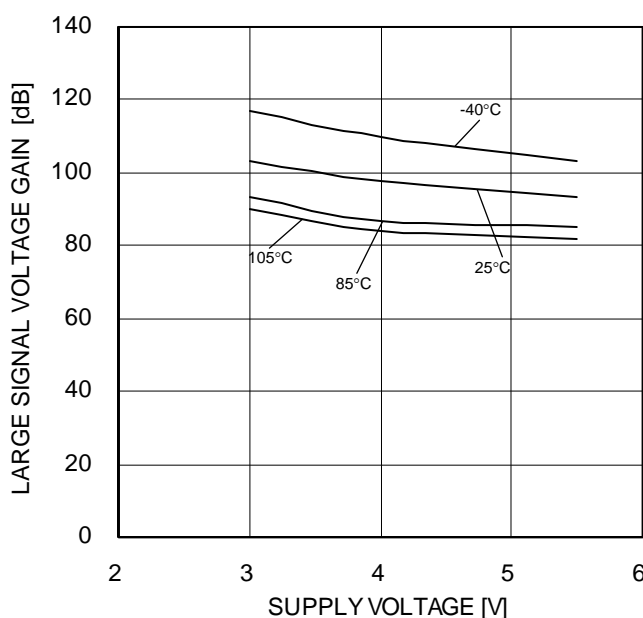


Figure 17.  
Large Signal Voltage Gain – Supply Voltage

(\*)The above characteristics are measurements of typical sample, they are not guaranteed.

BU7485G: -40°C to +85°C BU7485SG: -40°C to +105°C

# Typical Performance Curves - Continued

OBU7485G, BU7485SG

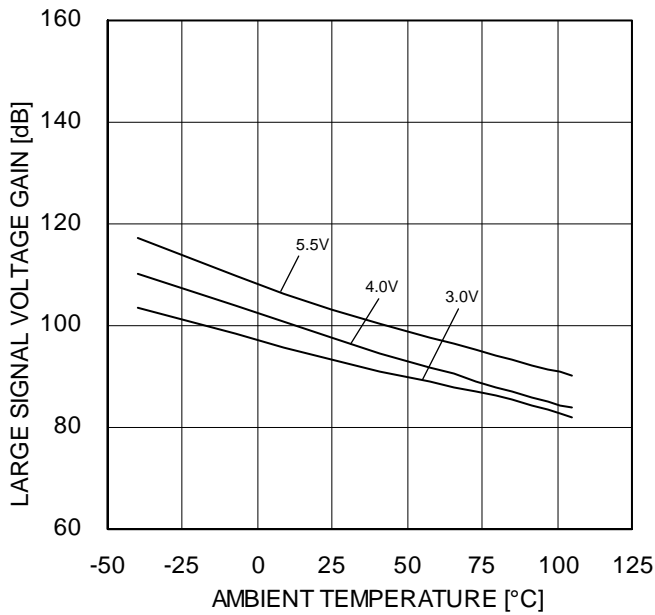


Figure 18  
Large Signal Voltage Gain – Ambient Temperature

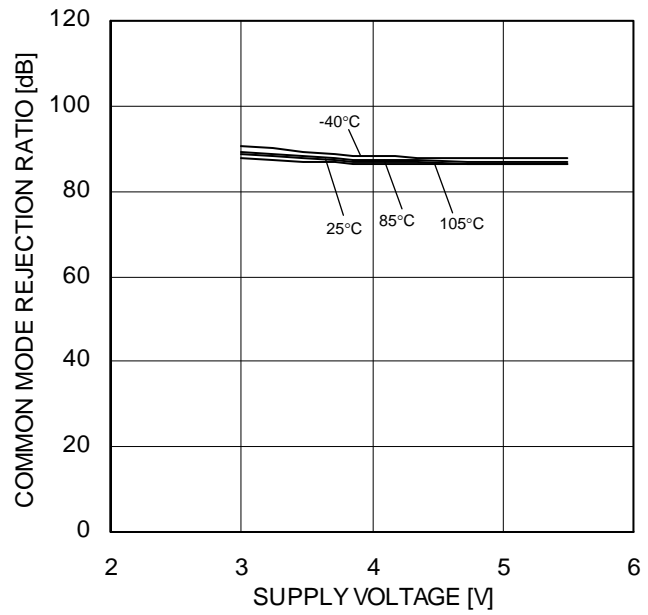


Figure 19.  
Common Mode Rejection Ratio – Supply Voltage

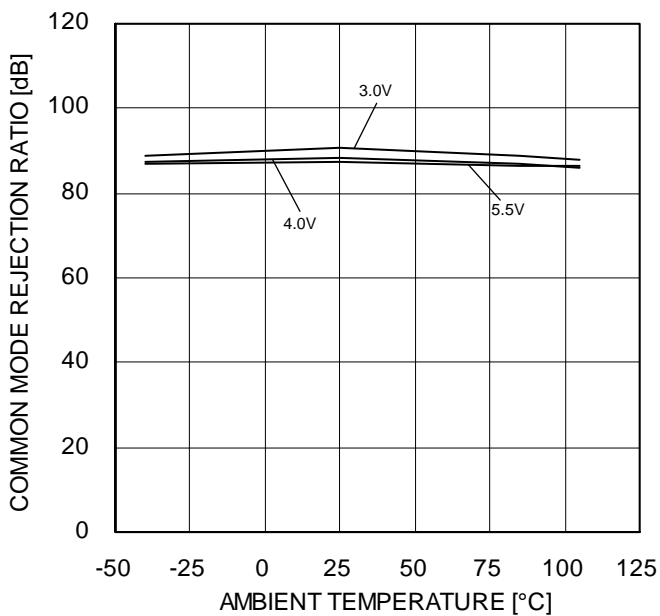


Figure 20.  
Common Mode Rejection Ratio – Ambient Temperature

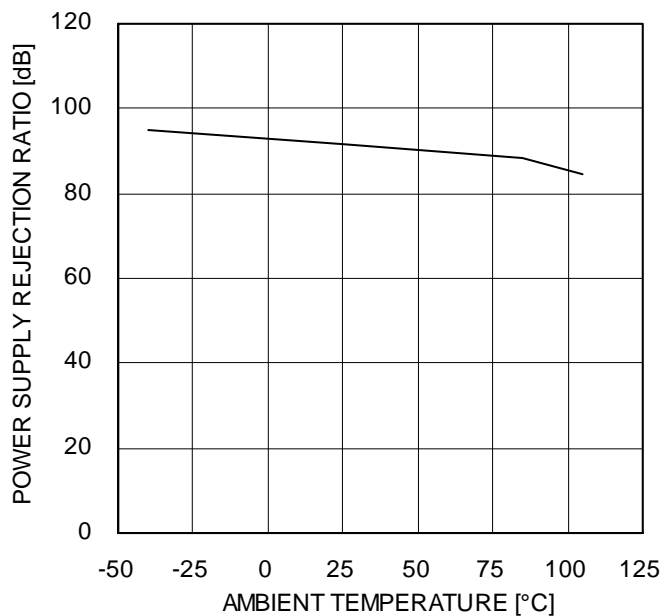


Figure 21.  
Power Supply Rejection Ratio – Ambient Temperature

(\*)The above characteristics are measurements of typical sample, they are not guaranteed.  
BU7485G: -40°C to +85°C BU7485SG: -40°C to +105°C

Typical Performance Curves - Continued

OBU7485G, BU7485SG

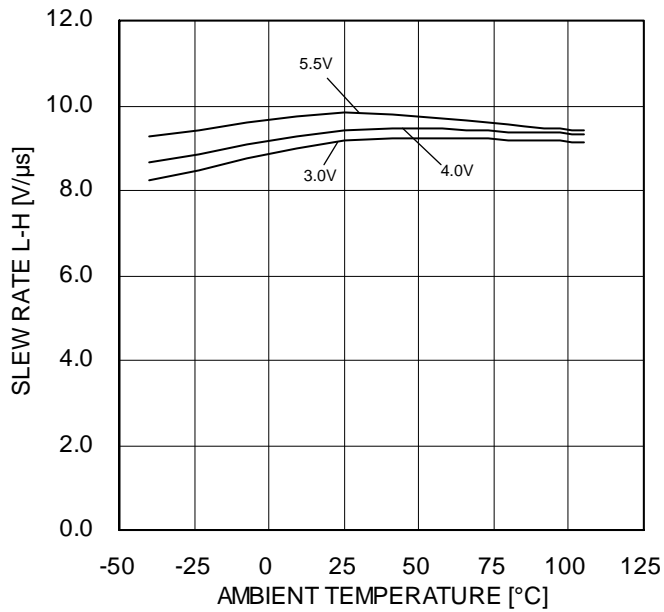


Figure 22.  
Slew Rate L-H – Ambient Temperature

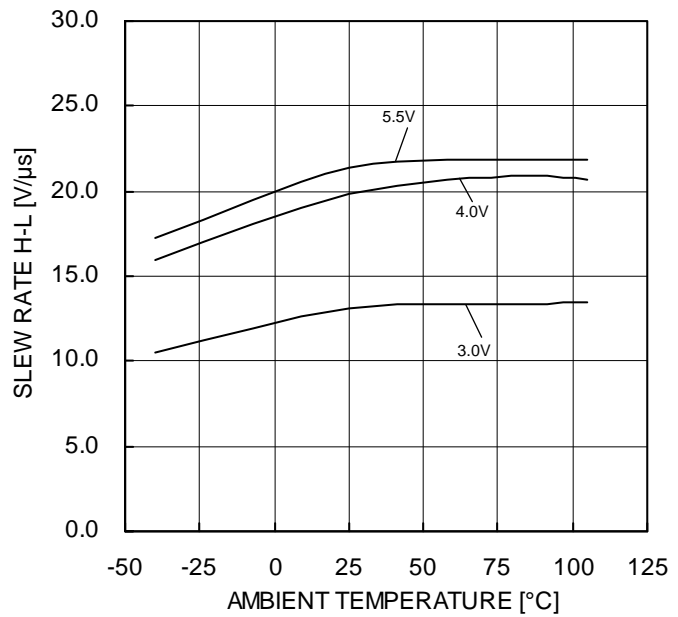


Figure 23.  
Slew Rate H-L – Ambient Temperature

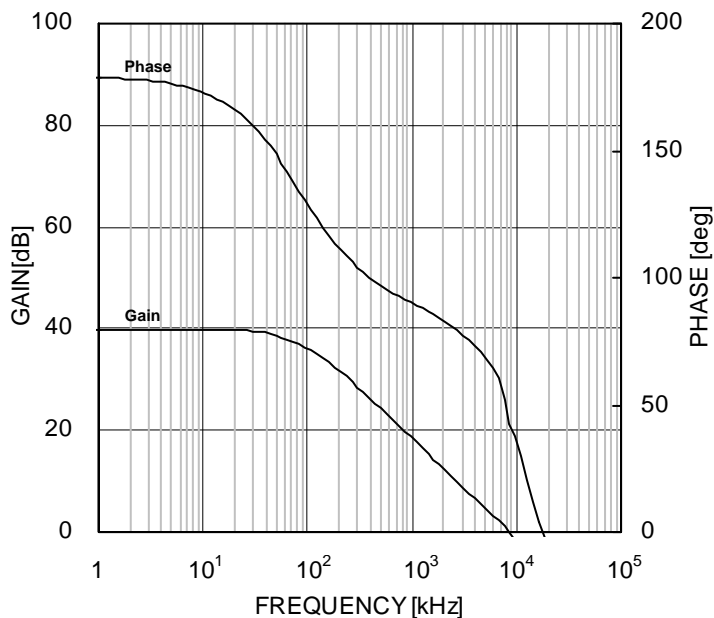


Figure 24.  
Voltage Gain • Phase—Frequency

(\*)The above characteristics are measurements of typical sample, they are not guaranteed.  
BU7485G: -40°C to +85°C BU7485SG: -40°C to +105°C

# Typical Performance Curves - Continued

OBU7486xxx, BU7486Sxxx

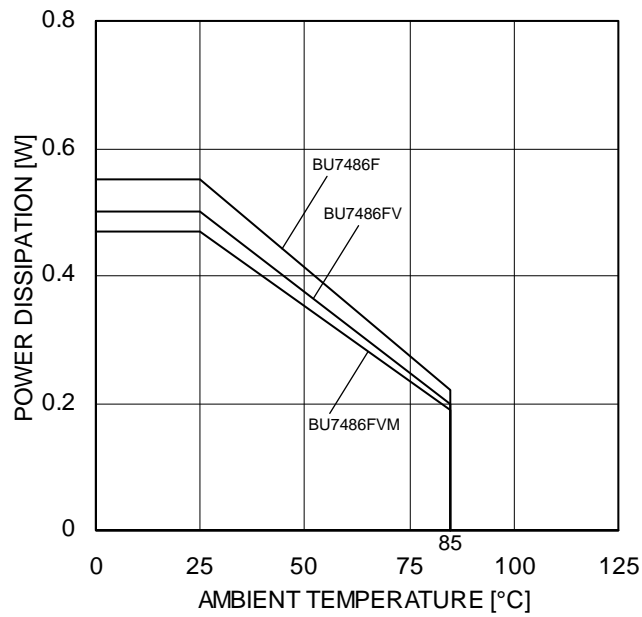


Figure 25.  
Derating curve

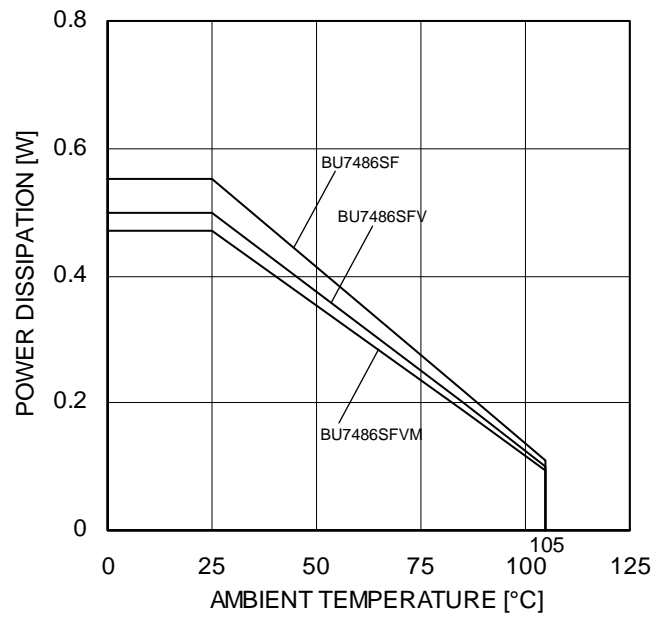


Figure 26.  
Derating curve

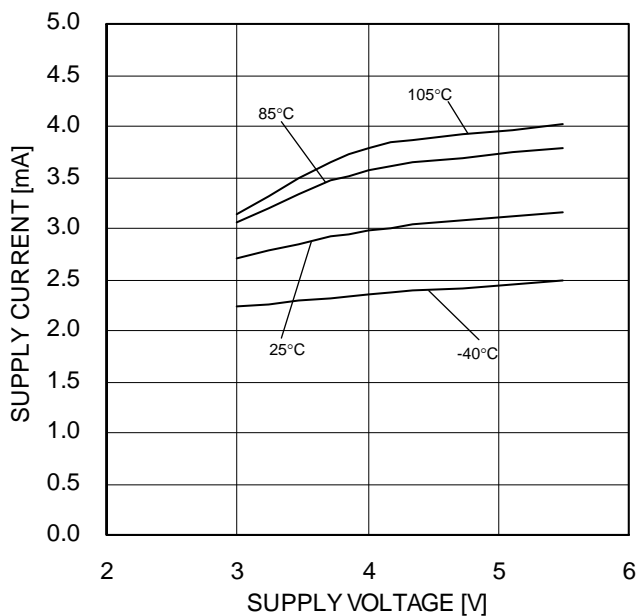


Figure 27.  
Supply Current – Supply Voltage

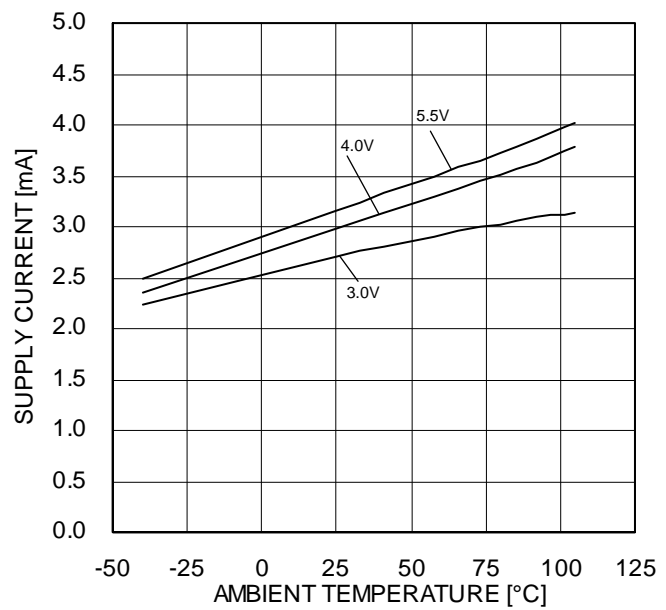


Figure 28.  
Supply Current – Ambient Temperature

(\*)The above characteristics are measurements of typical sample, they are not guaranteed.

BU7486xxx: -40°C to +85°C BU7486Sxxx: -40°C to +105°C

# Typical Performance Curves - Continued

OBU7486xxx, BU7486Sxxx

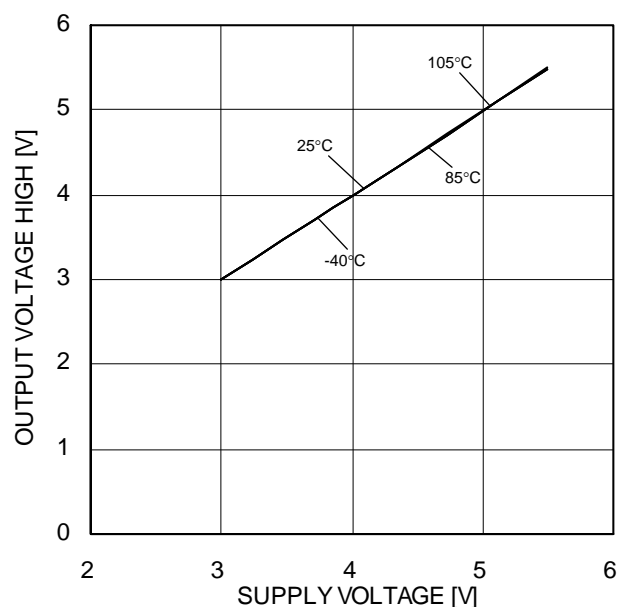


Figure 29.  
Maximum Output Voltage High –  
Supply Voltage  
( $R_L=10k\Omega$ )

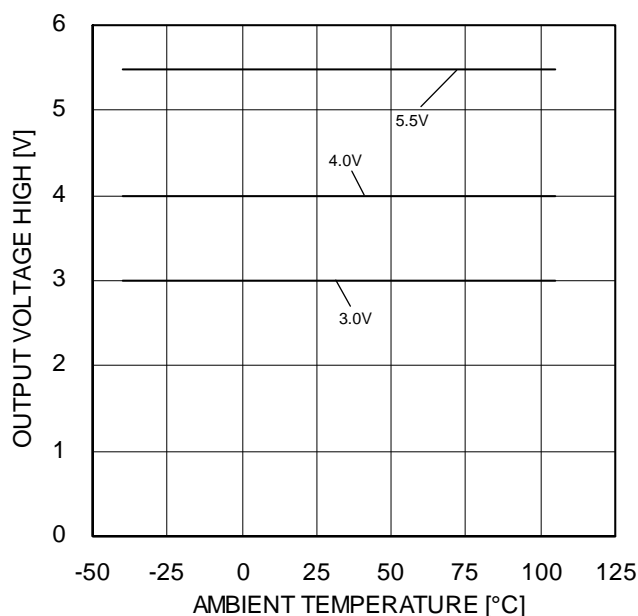


Figure 30.  
Maximum Output Voltage High –  
Ambient Temperature  
( $R_L=10k\Omega$ )

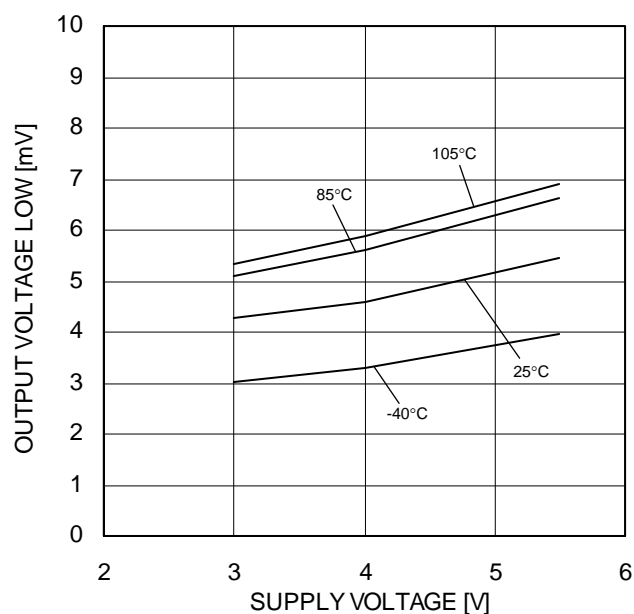


Figure 31.  
Maximum Output Voltage Low –  
Supply Voltage  
( $R_L=10k\Omega$ )

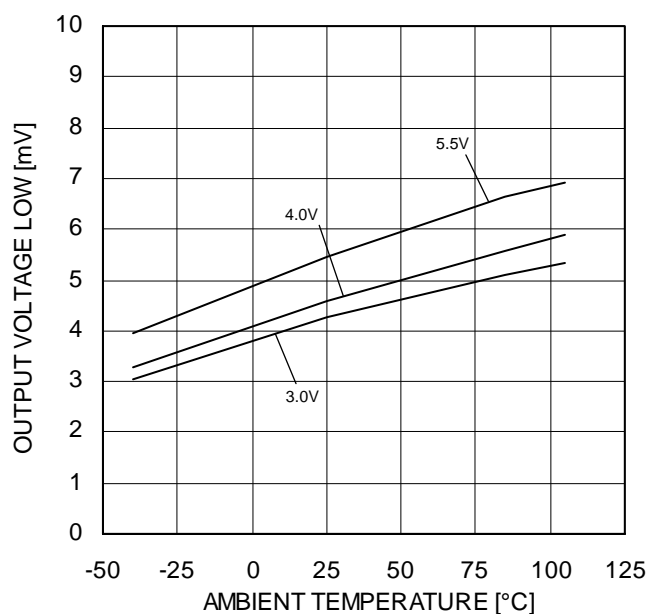


Figure 32.  
Maximum Output Voltage Low –  
Ambient Temperature  
( $R_L=10k\Omega$ )

(\*)The above characteristics are measurements of typical sample, they are not guaranteed.  
BU7486xxx: -40°C to +85°C BU7486Sxxx: -40°C to +105°C

# Typical Performance Curves - Continued

OBU7486xxx, BU7486Sxxx

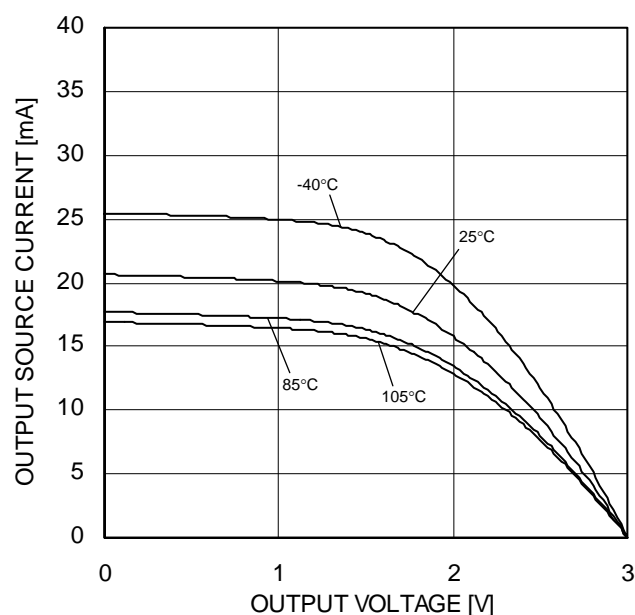


Figure 33.  
Output Source Current – Output Voltage  
(VDD=3V)

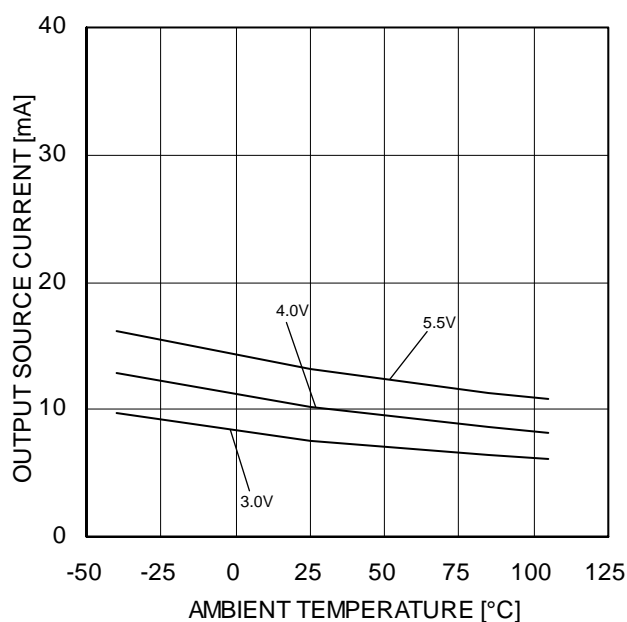


Figure 34.  
Output Source Current – Ambient Temperature  
(OUT=VDD-0.4V)

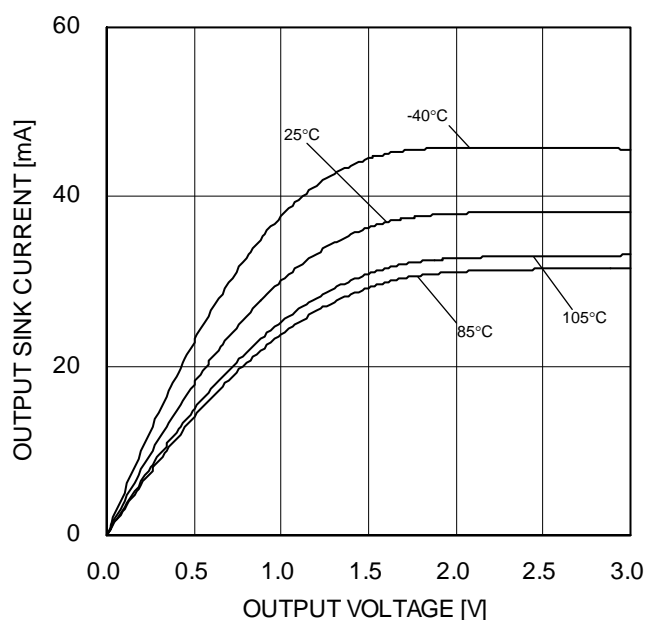


Figure 35.  
Output Sink Current – Output Voltage  
(VDD=3V)

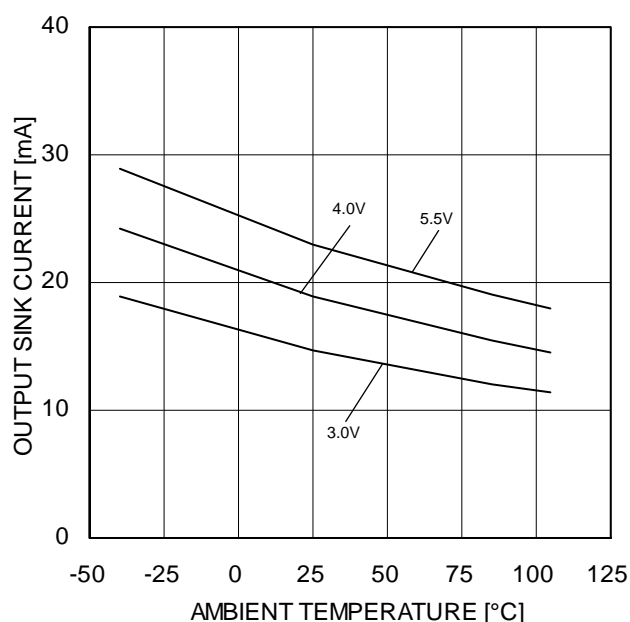


Figure 36.  
Output Sink Current – Ambient Temperature  
(OUT=VSS+0.4V)

(\*)The above characteristics are measurements of typical sample, they are not guaranteed.  
BU7486xxx: -40°C to +85°C BU7486Sxxx: -40°C to +105°C



# Typical Performance Curves - Continued

OBU7486xxx, BU7486Sxxx

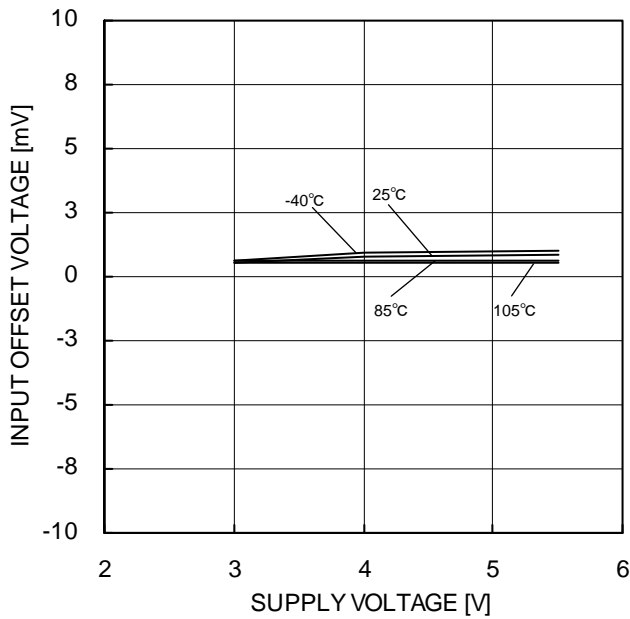


Figure 37.  
Input Offset Voltage – Supply Voltage

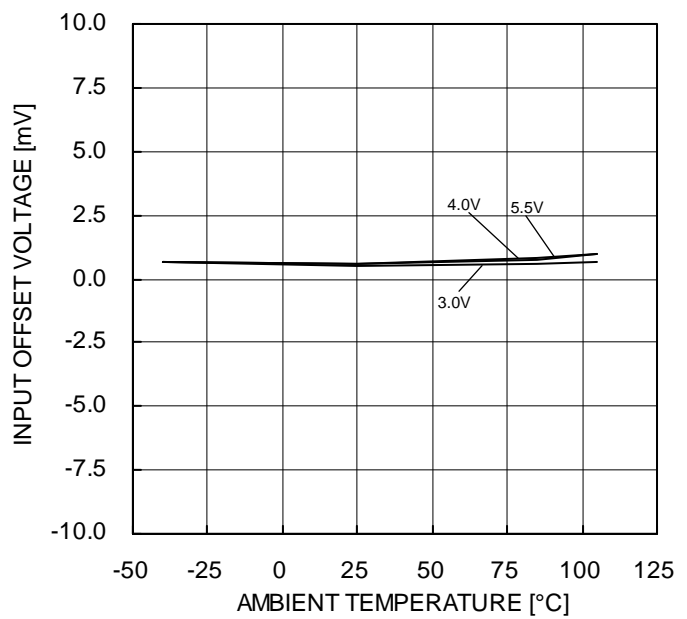


Figure 38.  
Input Offset Voltage – Ambient Temperature

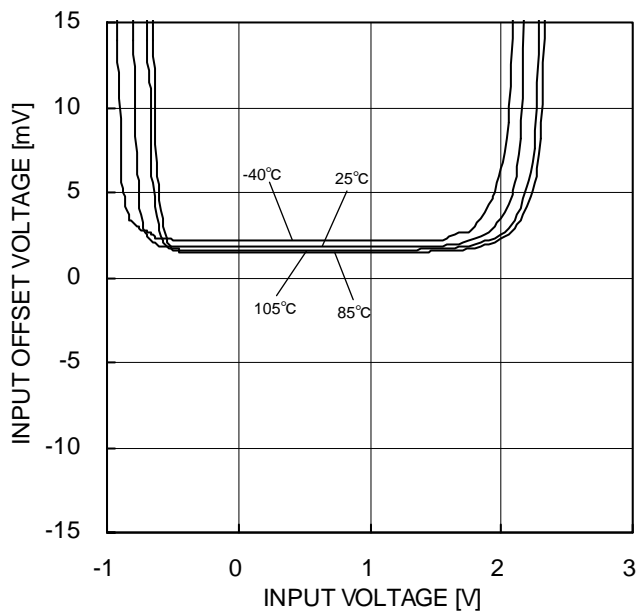


Figure 39.  
Input Offset Voltage – Common Mode  
Input Voltage  
(VDD=3V)

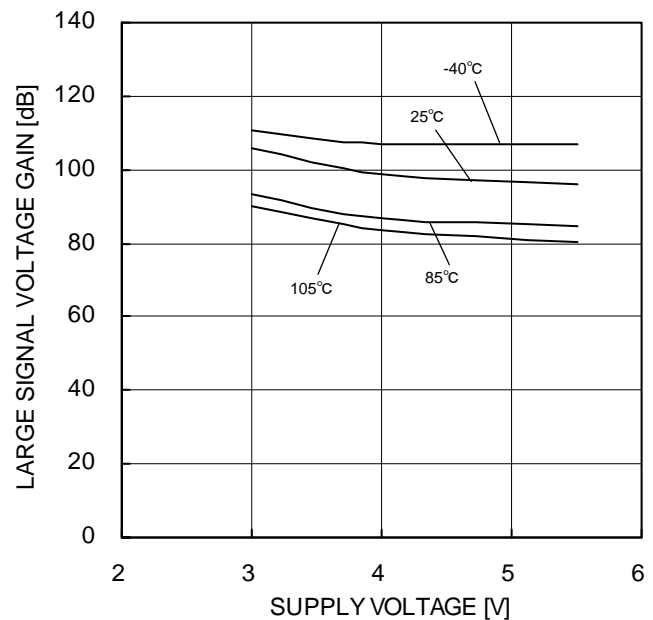


Figure 40.  
Large Signal Voltage Gain – Supply Voltage

(\*)The above characteristics are measurements of typical sample, they are not guaranteed.  
BU7486xxx: -40°C to +85°C BU7486Sxxx: -40°C to +105°C

Typical Performance Curves - Continued

OBU7486xxx, BU7486Sxxx

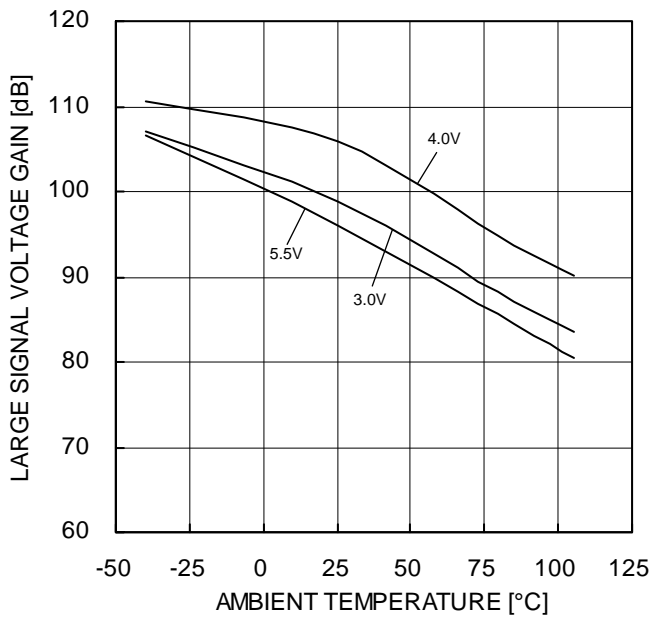


Figure 41.  
Large Signal Voltage Gain –  
Ambient Temperature

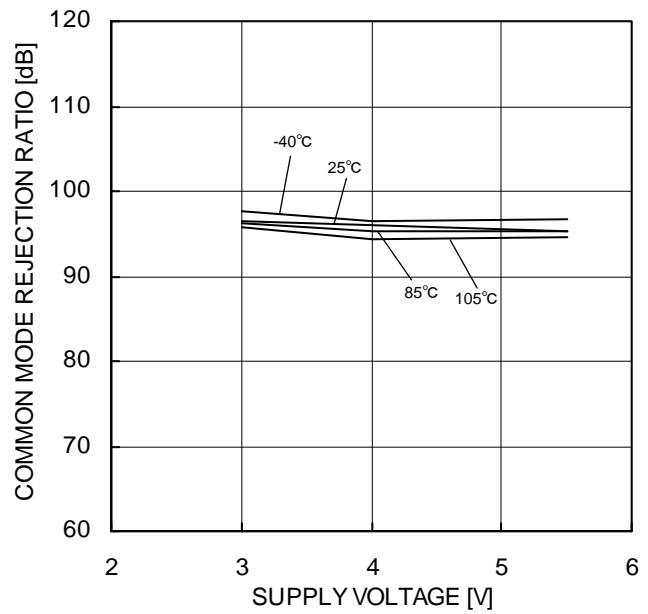


Figure 42.  
Common Mode Rejection Ratio – Supply Voltage

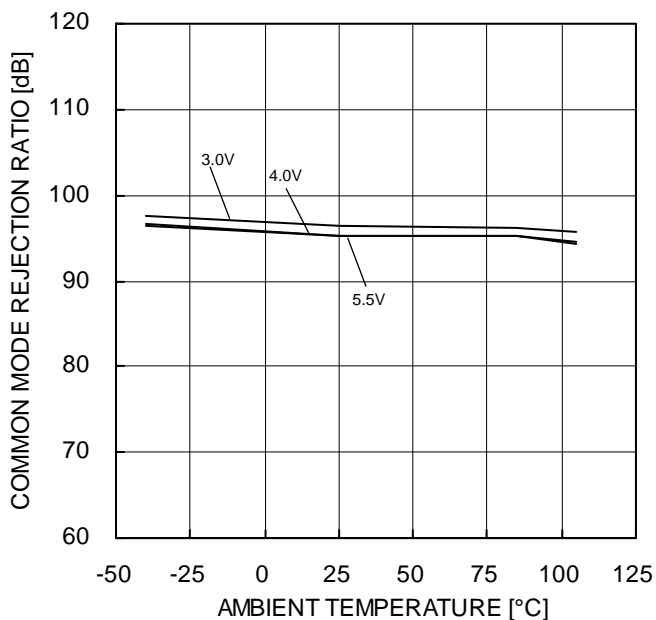


Figure 43.  
Common Mode Rejection Ratio –  
Ambient Temperature

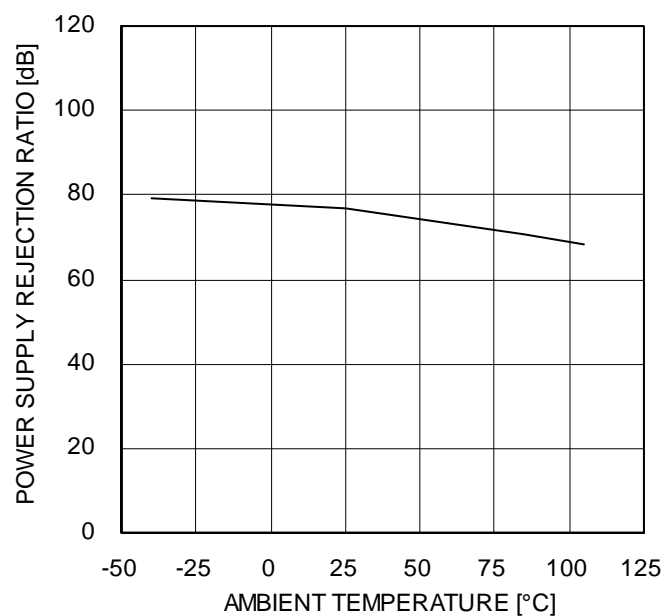


Figure 44.  
Power Supply Rejection Ratio –  
Ambient Temperature

(\*)The above characteristics are measurements of typical sample, they are not guaranteed.  
BU7486xxx: -40°C to +85°C BU7486Sxxx: -40°C to +105°C

# Typical Performance Curves - Continued

OBU7486xxx, BU7486Sxxx

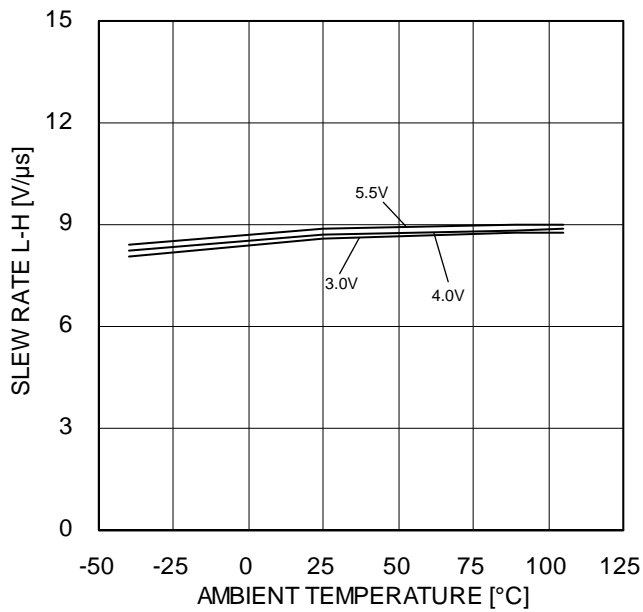


Figure 45.  
Slew Rate L-H – Ambient Temperature

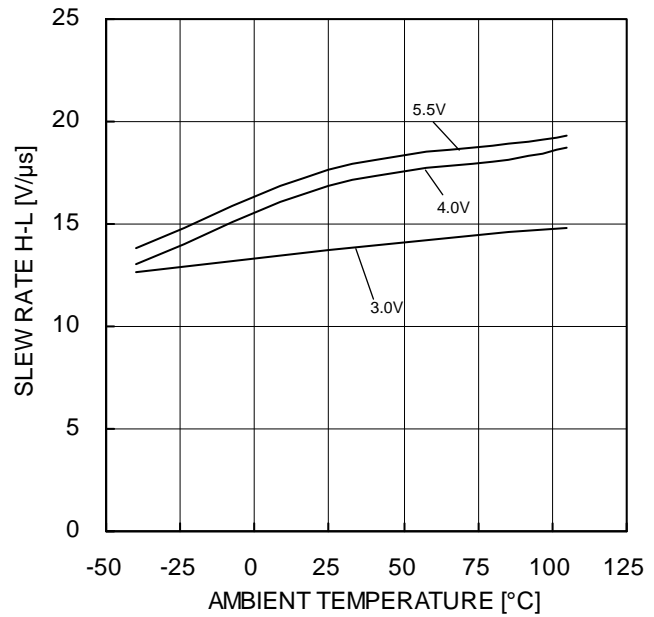


Figure 46.  
Slew Rate H-L – Ambient Temperature

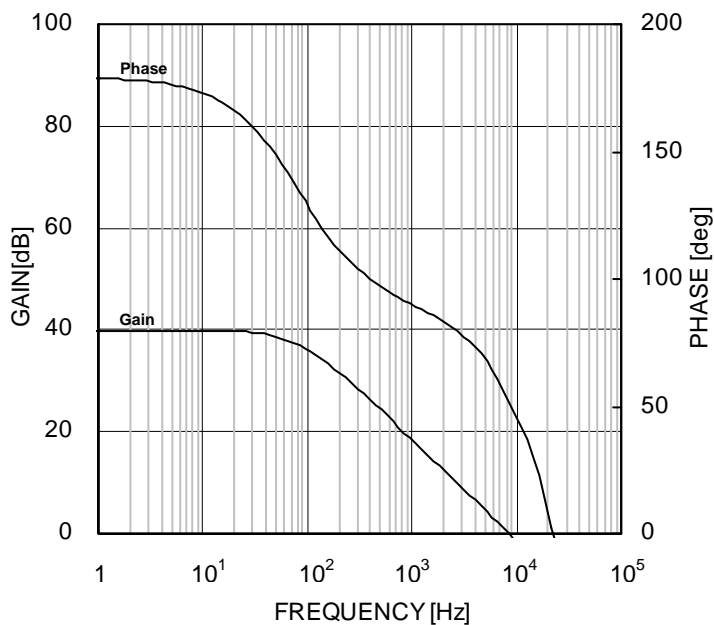


Figure 47.  
Voltage Gain • Phase—Frequency

(\*)The above characteristics are measurements of typical sample, they are not guaranteed.  
BU7486xxx: -40°C to +85°C BU7486Sxxx: -40°C to +105°C

# Typical Performance Curves

OBU7487xx, BU7487Sxx

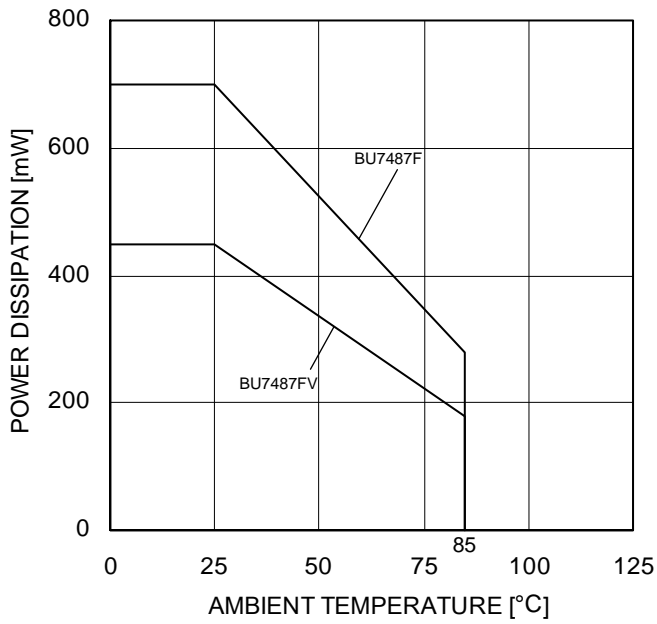


Figure 48.  
Derating curve

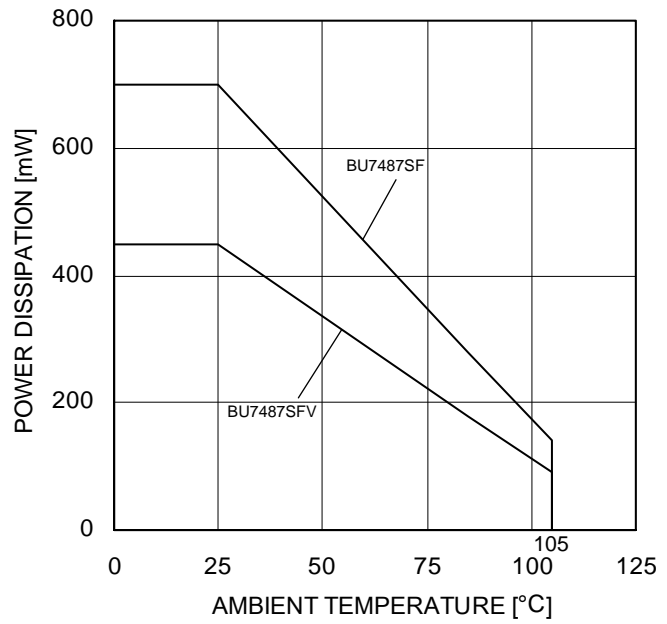


Figure 49.  
Derating curve

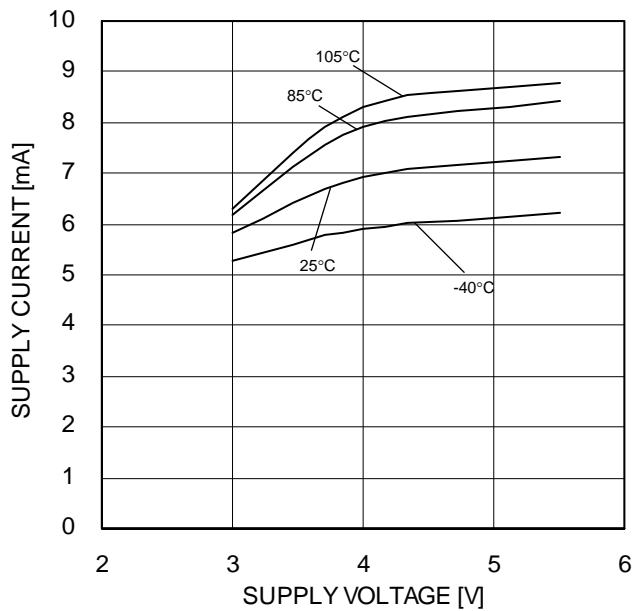


Figure 50.  
Supply Current – Supply Voltage

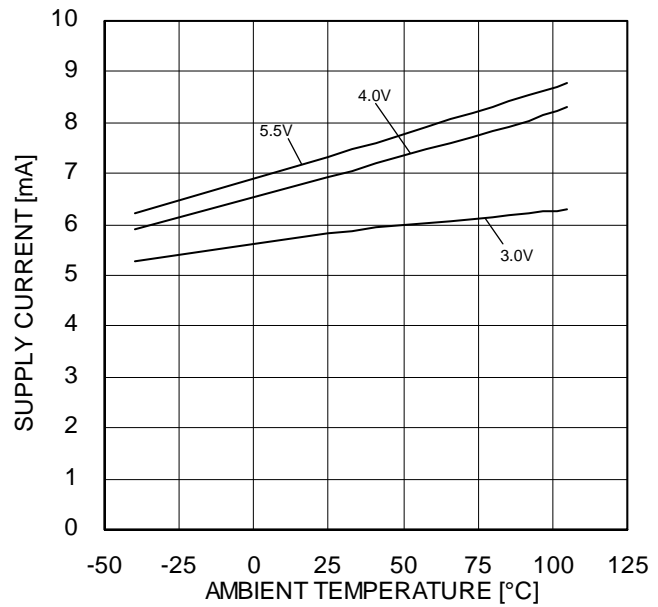


Figure 51.  
Supply Current – Ambient Temperature

(\*)The above characteristics are measurements of typical sample, they are not guaranteed.  
BU7487xx: -40°C to +85°C BU7487Sxx: -40°C to +105°C

Typical Performance Curves - Continued

OBU7487xx, BU7487Sxx

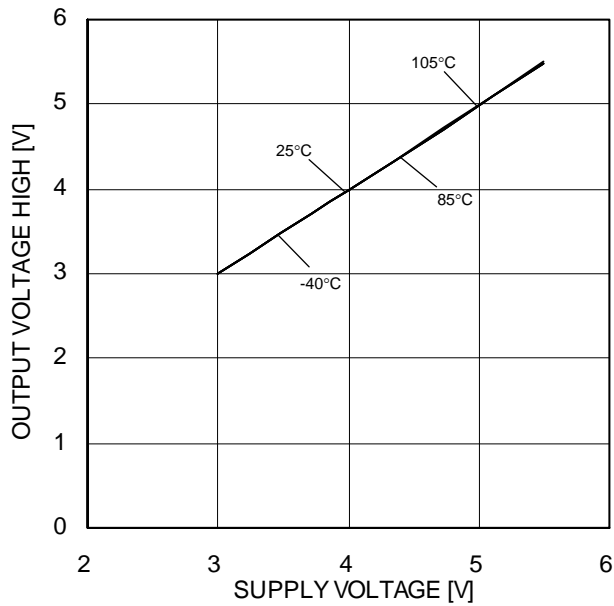


Figure 52.  
Maximum Output Voltage High – Supply Voltage  
( $R_L=10k\Omega$ )

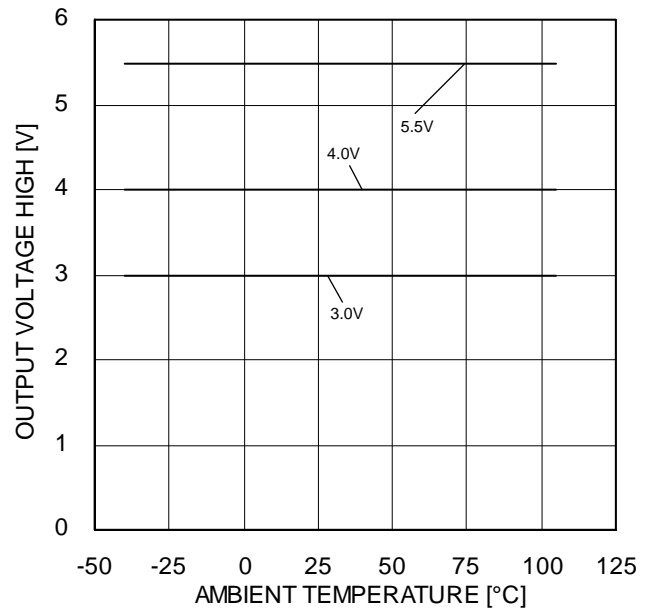


Figure 53.  
Maximum Output Voltage High – Ambient Temperature  
( $R_L=10k\Omega$ )

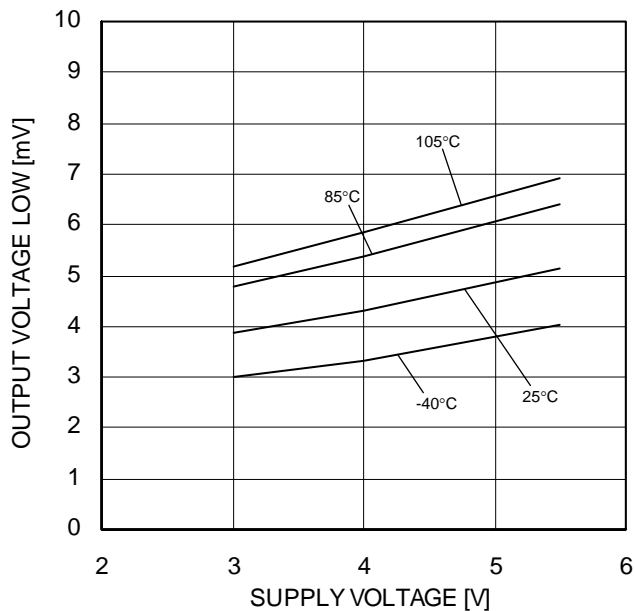


Figure 54.  
Maximum Output Voltage Low – Supply Voltage  
( $R_L=10k\Omega$ )

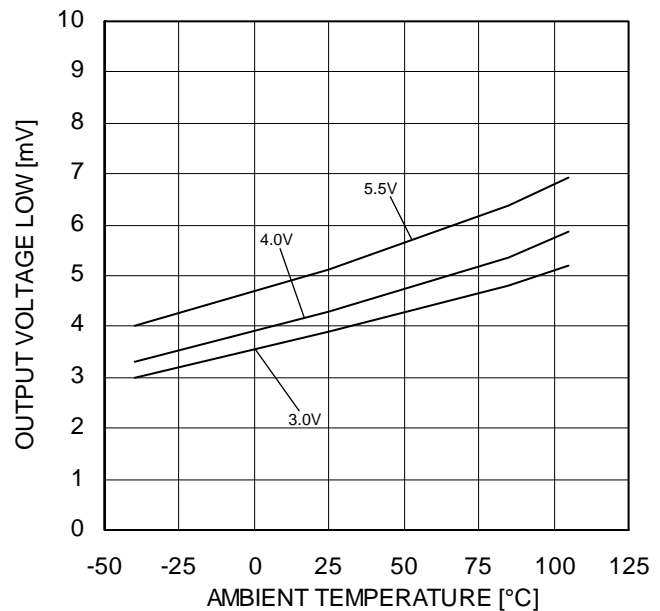


Figure 55.  
Maximum Output Voltage Low – Ambient Temperature  
( $R_L=10k\Omega$ )

(\*)The above characteristics are measurements of typical sample, they are not guaranteed.

BU7487xx: -40°C to +85°C BU7487Sxx: -40°C to +105°C

# Typical Performance Curves - Continued

OB7487xx, BU7487Sxx

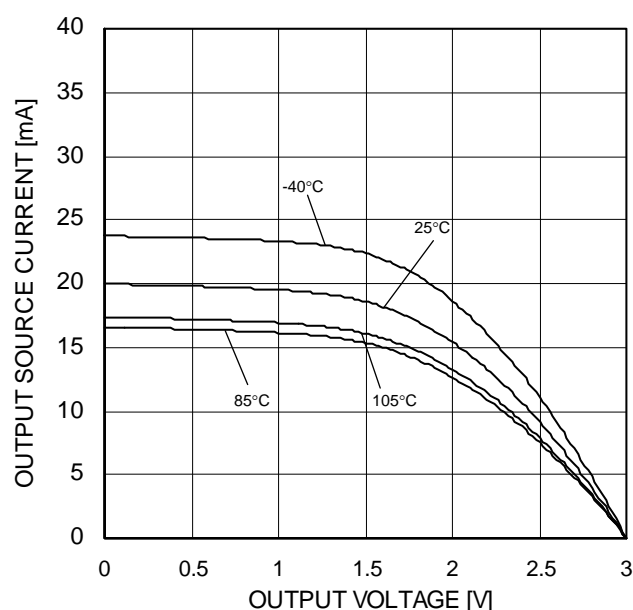


Figure 56.  
Output Source Current – Output Voltage  
(VDD=3V)

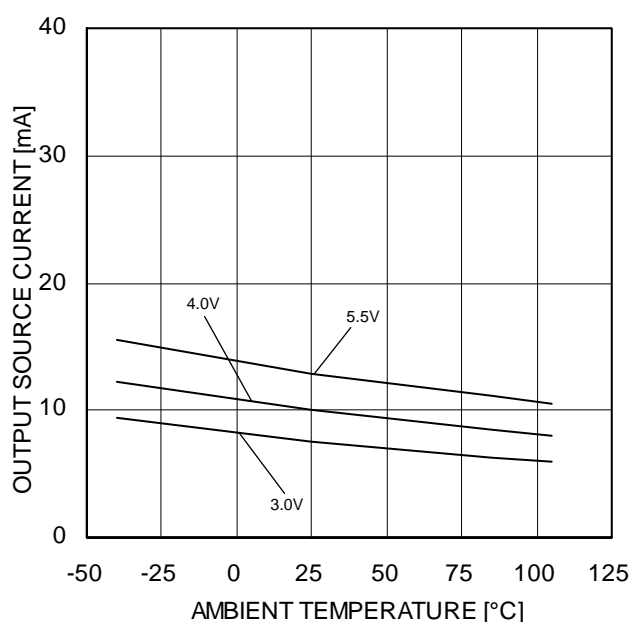


Figure 57.  
Output Source Current – Ambient Temperature  
(OUT=VDD-0.4V)

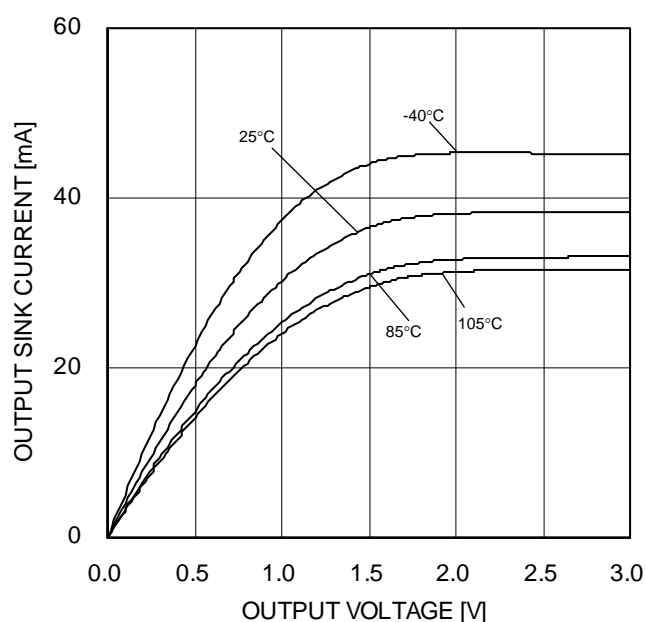


Figure 58.  
Output Sink Current – Output Voltage  
(VDD=3V)

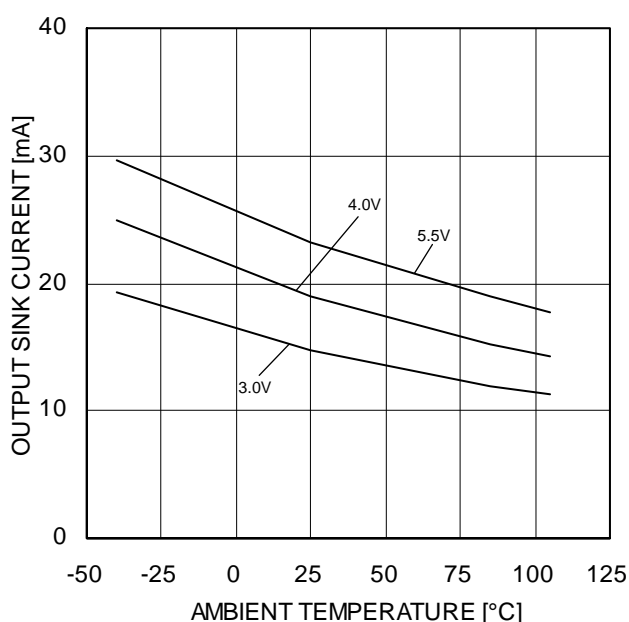


Figure 59.  
Output Sink Current – Ambient Temperature  
(OUT=VSS+0.4V)

(\*)The above characteristics are measurements of typical sample, they are not guaranteed.

BU7487xx: -40°C to +85°C BU7487Sxx: -40°C to +105°C

# Typical Performance Curves - Continued

OBU7487xx, BU7487Sxx

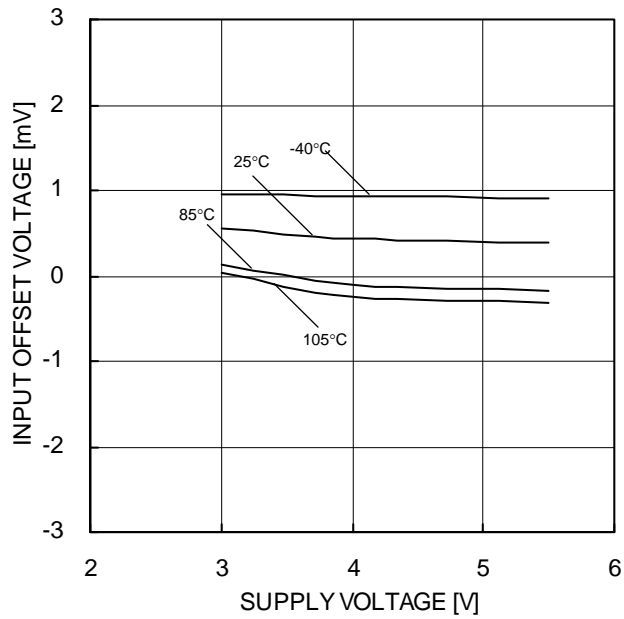


Figure 60.  
Input Offset Voltage – Supply Voltage

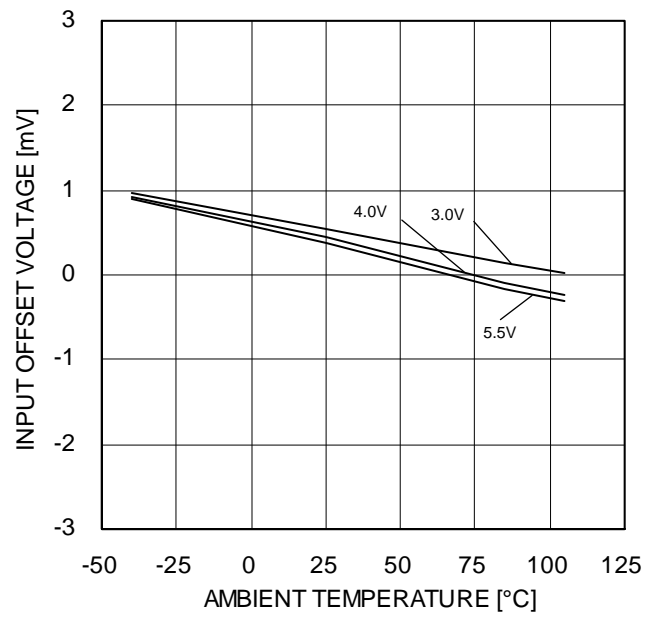


Figure 61.  
Input Offset Voltage – Ambient Temperature

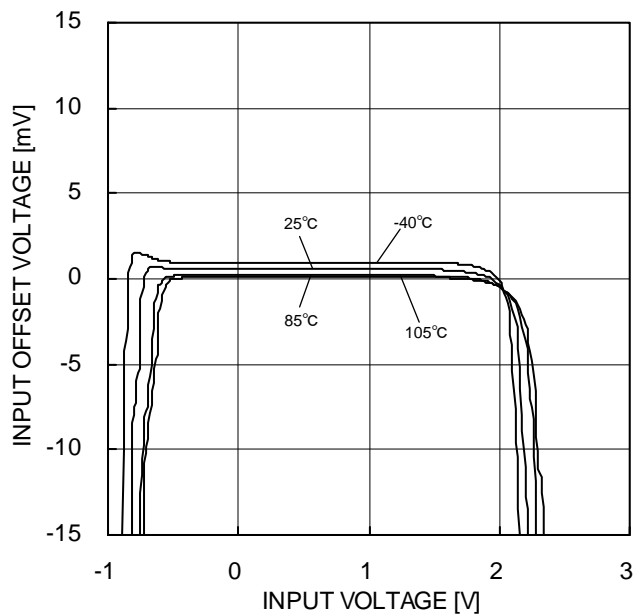


Figure 62.  
Input Offset Voltage –  
Common Mode Input Voltage  
(VDD=3V)

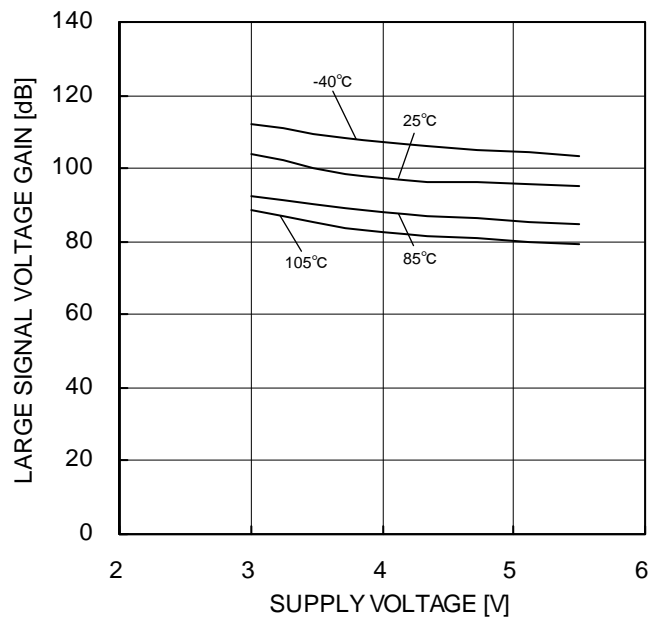


Figure 63.  
Large Signal Voltage Gain – Supply Voltage

(\*)The above characteristics are measurements of typical sample, they are not guaranteed.

BU7487xx: -40°C to +85°C BU7487Sxx: -40°C to +105°C

# Typical Performance Curves - Continued

OBU7487xx, BU7487Sxx

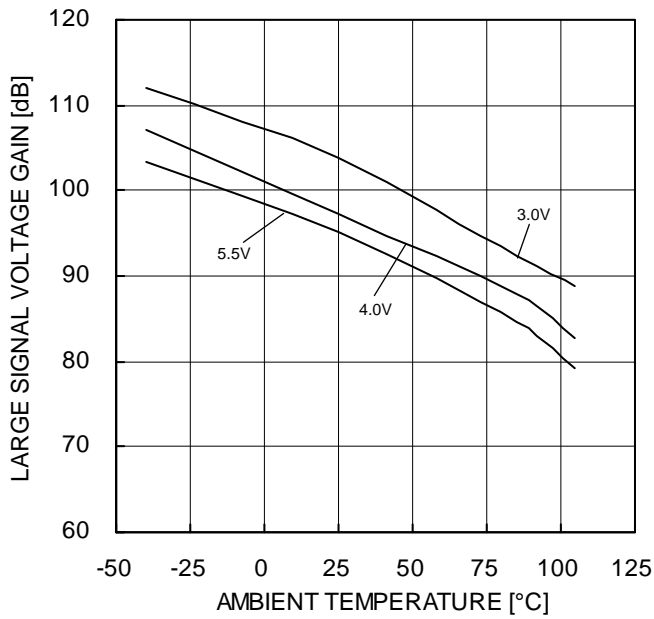


Figure 64.

Large Signal Voltage Gain – Ambient Temperature

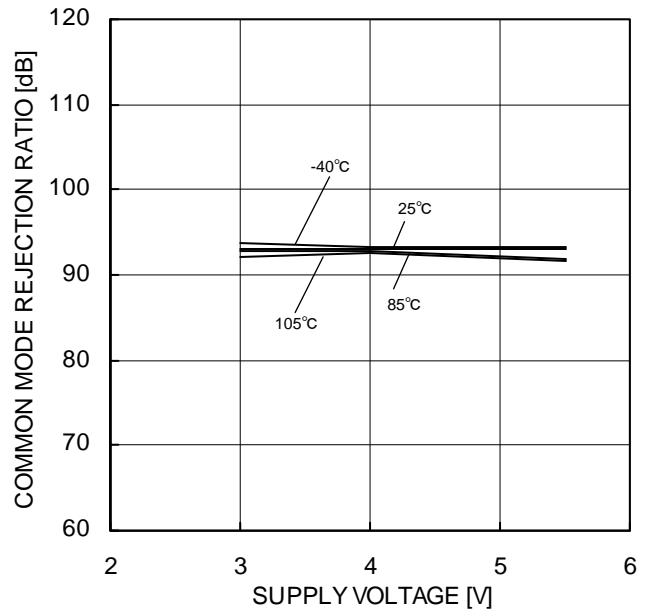


Figure 65.

Common Mode Rejection Ratio – Supply Voltage

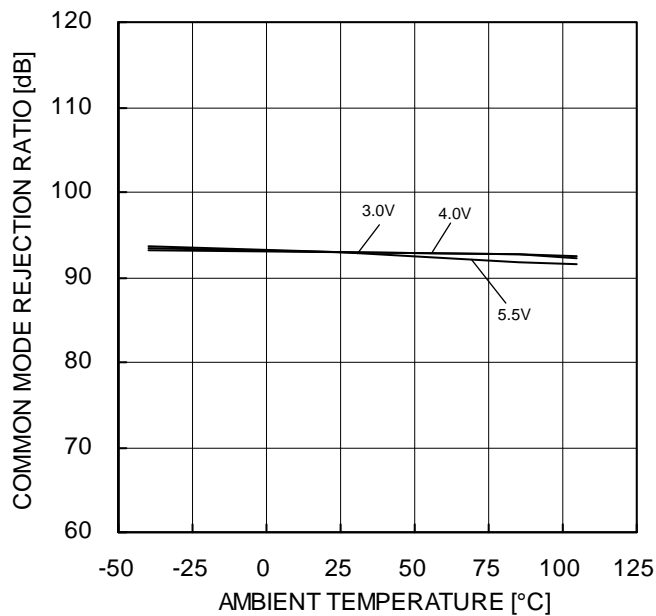


Figure 66.

Common Mode Rejection Ratio – Ambient Temperature

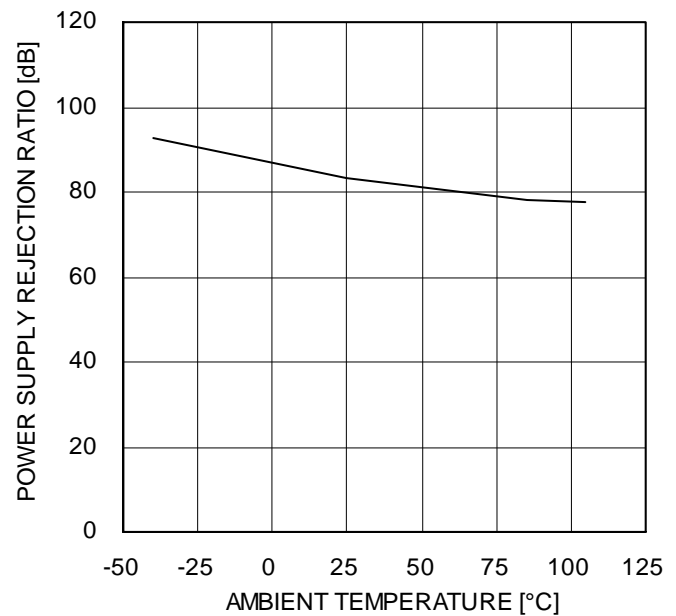


Figure 67.

Power Supply Rejection Ratio – Ambient Temperature

(\*)The above characteristics are measurements of typical sample, they are not guaranteed.

BU7487xx: -40°C to +85°C BU7487Sxx: -40°C to +105°C



# Typical Performance Curves - Continued

OBU7487xx, BU7487Sxx

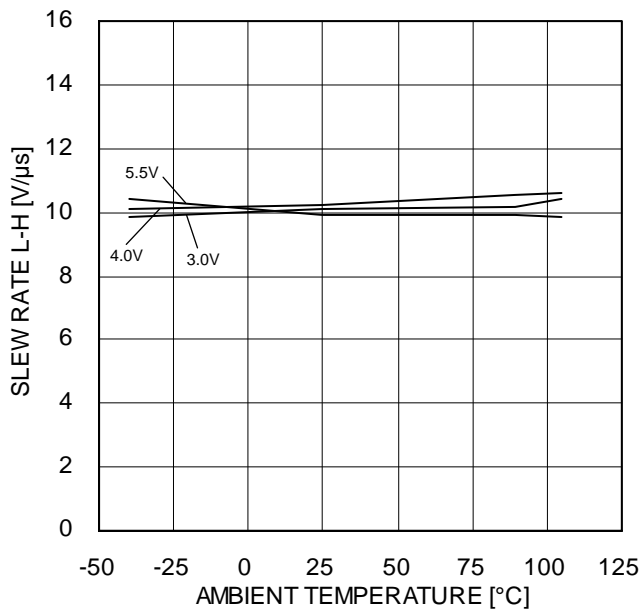


Figure 68.  
Slew Rate L-H – Ambient Temperature

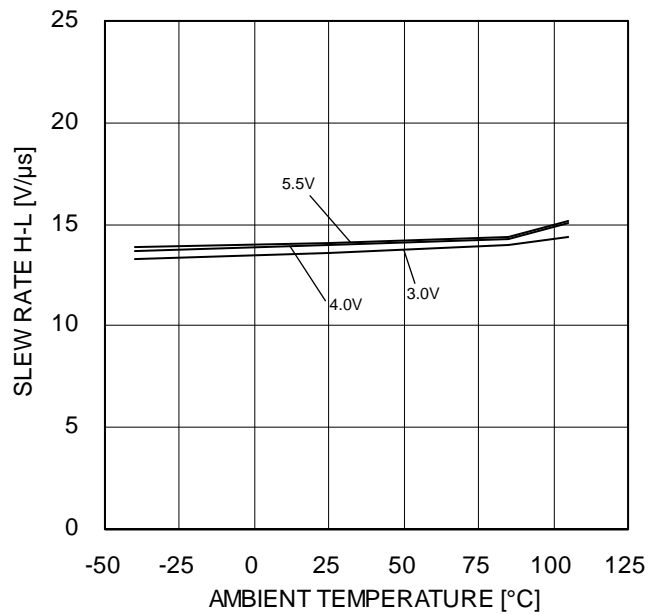


Figure 69.  
Slew Rate H-L – Ambient Temperature

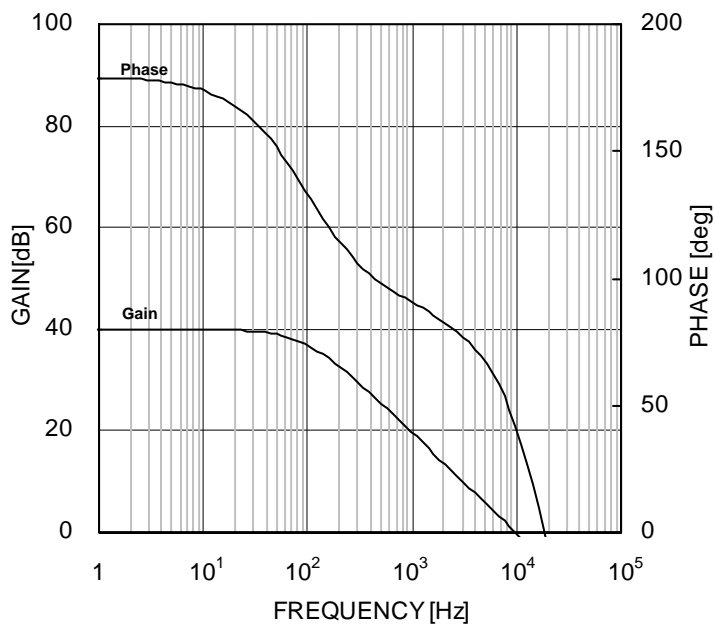


Figure 70.  
Voltage Gain • Phase—Frequency

(\*)The above characteristics are measurements of typical sample, they are not guaranteed.

BU7487xx: -40°C to +85°C BU7487Sxx: -40°C to +105°C

Application Information  
NULL method condition for Test circuit1

VDD, VSS, EK, Vicm Unit:V

Parameter	VF	S1	S2	S3	VDD	VSS	EK	Vicm	Calculation
Input Offset Voltage	VF1	ON	ON	OFF	3	0	-1.5	1.8	1
Large Signal Voltage Gain	VF2	ON	ON	ON	3	0	-0.5	0.9	2
	VF3						-2.5		
Common-mode Rejection Ratio (Input Common-mode Voltage Range)	VF4	ON	ON	OFF	3	0	-1.5	0	3
	VF5							1.8	
Power Supply Rejection Ratio	VF6	ON	ON	OFF	3	0	-0.9	0	4
	VF7				5.5				

—Calculation—

1. Input Offset Voltage (Vio)

$$V_{io} = \frac{|VF1|}{1+R_F/R_S} \text{ [V]}$$
2. Large Signal Voltage Gain (Av)

$$A_v = 20\text{Log} \frac{2 \times (1+R_F/R_S)}{|VF2-VF3|} \text{ [dB]}$$
3. Common-mode Rejection Ratio (CMRR)

$$\text{CMRR} = 20\text{Log} \frac{1.8 \times (1+R_F/R_S)}{|VF4 - VF5|} \text{ [dB]}$$
4. Power Supply Rejection Ratio (PSRR)

$$\text{PSRR} = 20\text{Log} \frac{2.5 \times (1+R_F/R_S)}{|VF6 - VF7|} \text{ [dB]}$$

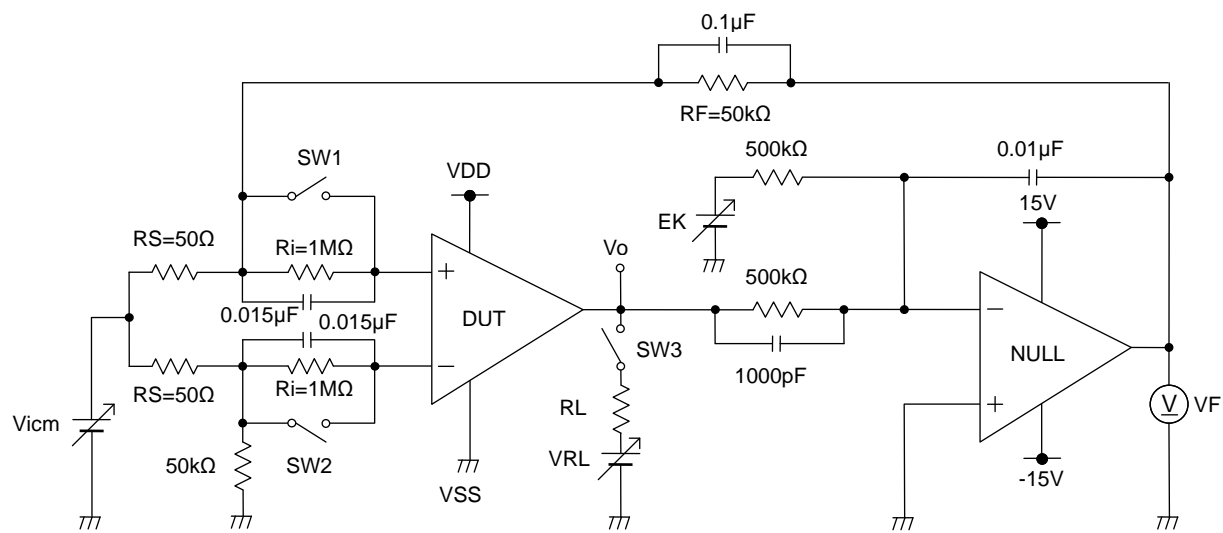


Figure 71. Test circuit 1 (one channel only)

Switch Condition for Test circuit2

SW No.	SW1	SW2	SW3	SW4	SW5	SW6	SW7	SW8	SW9	SW10	SW11	SW12
Supply Current	OFF	OFF	ON	OFF	ON	OFF	OFF	OFF	OFF	OFF	OFF	OFF
Maximum Output Voltage RL=10kΩ	OFF	ON	OFF	OFF	ON	OFF	OFF	ON	OFF	OFF	ON	OFF
Output Current	OFF	ON	OFF	OFF	ON	OFF	OFF	OFF	OFF	ON	OFF	OFF
Slew Rate	OFF	OFF	ON	OFF	OFF	OFF	ON	OFF	ON	OFF	OFF	ON
Unity Gain Frequency	ON	OFF	OFF	ON	ON	OFF	OFF	OFF	ON	OFF	OFF	ON

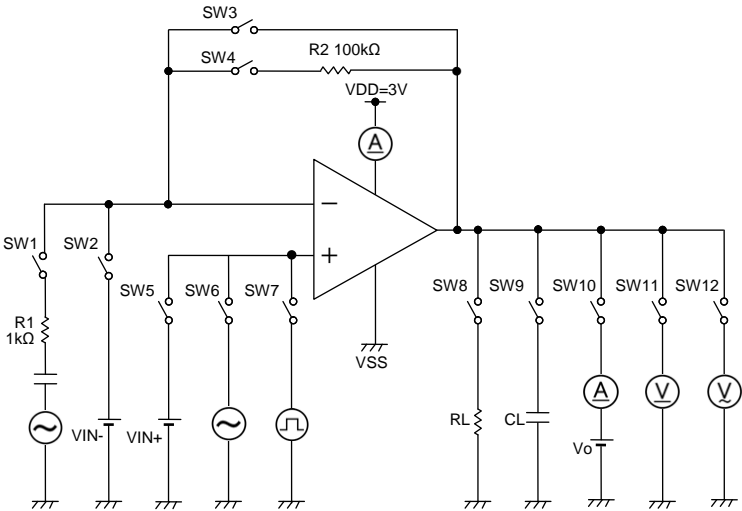


Figure 72. Test circuit 2

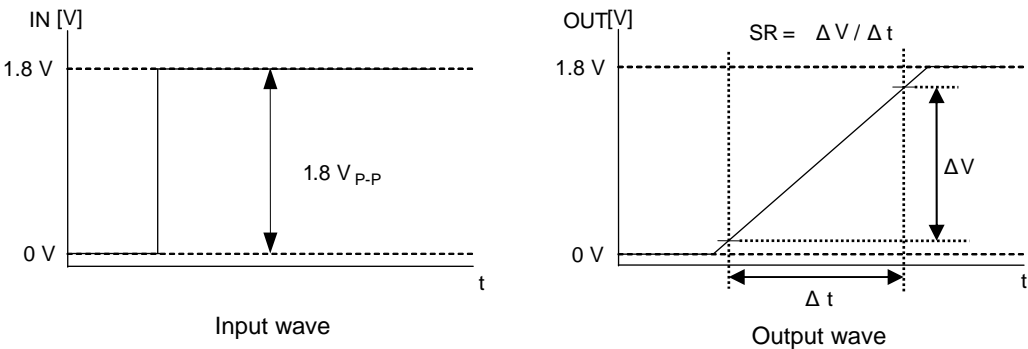


Figure 73. Slew rate input output wave

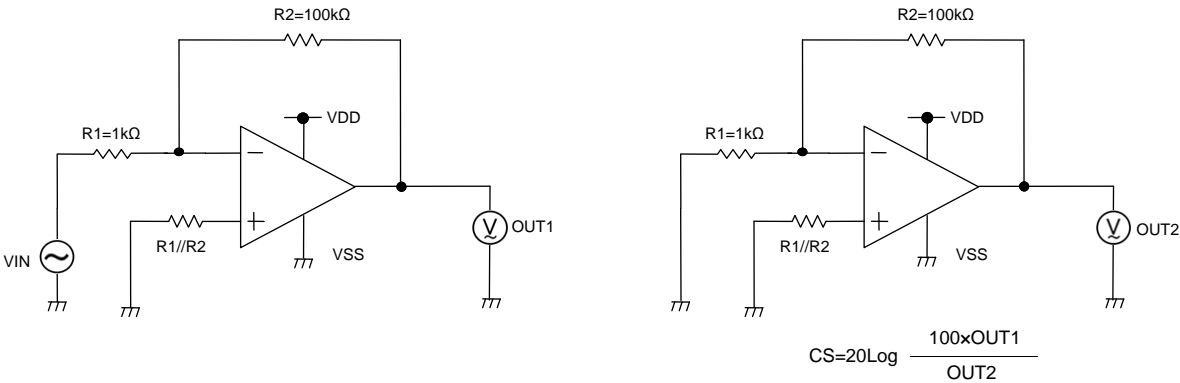
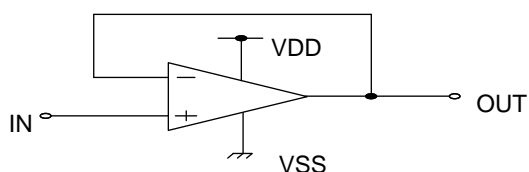


Figure 74. Test circuit 3 (Channel Separation)

**Application example**

## ○Voltage follower



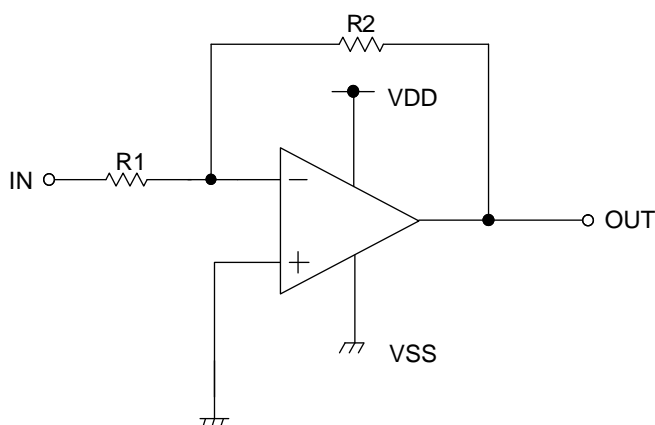
Voltage gain is 0dB.

Using this circuit, the output voltage (OUT) is configured to be equal to the input voltage (IN). This circuit also stabilizes the output voltage (OUT) due to high input impedance and low output impedance. Computation for output voltage (OUT) is shown below.

$$OUT = IN$$

Figure 75. Voltage follower

## ○Inverting amplifier



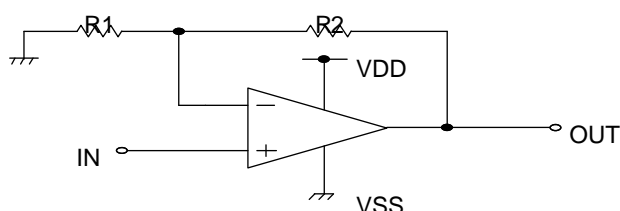
For inverting amplifier, input voltage (IN) is amplified by a voltage gain and depends on the ratio of R1 and R2. The out-of-phase output voltage is shown in the next expression

$$OUT = -(R2/R1) \cdot IN$$

This circuit has input impedance equal to R1.

Figure 76. Inverting amplifier circuit

## ○Non-inverting amplifier



For non-inverting amplifier, input voltage (IN) is amplified by a voltage gain, which depends on the ratio of R1 and R2. The output voltage (OUT) is in-phase with the input voltage (IN) and is shown in the next expression.

$$OUT = (1 + R2/R1) \cdot IN$$

Effectively, this circuit has high input impedance since its input side is the same as that of the operational amplifier.

Figure 77. Non-inverting amplifier circuit

## Power Dissipation

Power dissipation (total loss) indicates the power that the IC can consume at  $T_a=25^{\circ}\text{C}$  (normal temperature). As the IC consumes power, it heats up, causing its temperature to be higher than the ambient temperature. The allowable temperature that the IC can accept is limited. This depends on the circuit configuration, manufacturing process, and consumable power.

Power dissipation is determined by the allowable temperature within the IC (maximum junction temperature) and the thermal resistance of the package used (heat dissipation capability). Maximum junction temperature is typically equal to the maximum storage temperature. The heat generated through the consumption of power by the IC radiates from the mold resin or lead frame of the package. Thermal resistance, represented by the symbol  $\theta_{ja}^{\circ}\text{C/W}$ , indicates this heat dissipation capability. Similarly, the temperature of an IC inside its package can be estimated by thermal resistance.

Figure 78. (a) shows the model of the thermal resistance of a package. The equation below shows how to compute for the Thermal resistance ( $\theta_{ja}$ ), given the ambient temperature ( $T_a$ ), maximum junction temperature ( $T_{jmax}$ ), and power dissipation ( $P_d$ ).

$$\theta_{ja} = (T_{jmax} - T_a) / P_d \quad ^{\circ}\text{C/W} \quad \dots \quad (I)$$

The Derating curve in Figure 78. (b) indicates the power that the IC can consume with reference to ambient temperature. Power consumption of the IC begins to attenuate at certain temperatures. This gradient is determined by Thermal resistance ( $\theta_{ja}$ ), which depends on the chip size, power consumption, package, ambient temperature, package condition, wind velocity, etc. This may also vary even when the same of package is used. Thermal reduction curve indicates a reference value measured at a specified condition. Figure 79. (c) to (h) shows an example of the derating curve for BU7485G, BU7485SG, BU7486xxx, BU7486Sxxx, BU7487xx, BU7487Sxx.

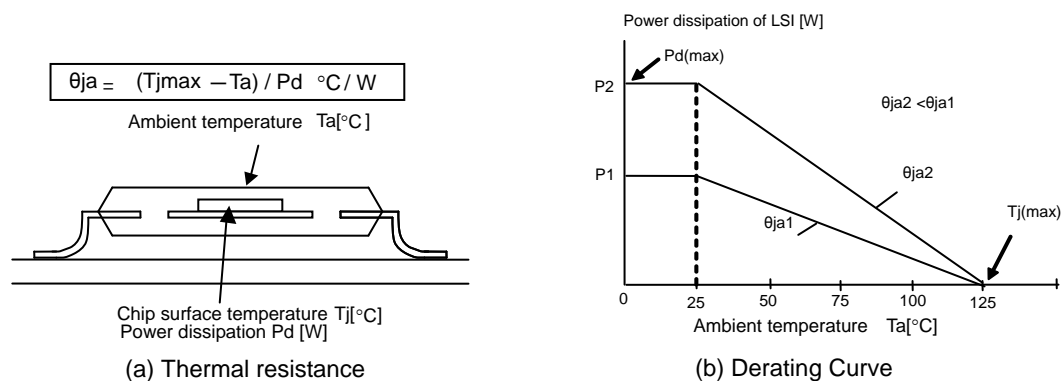
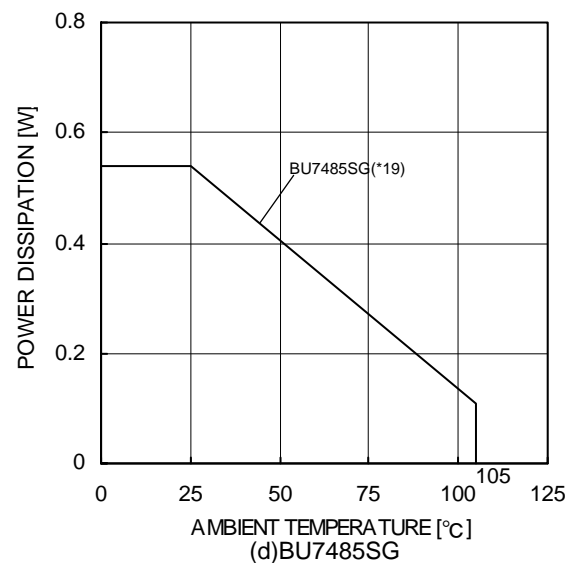
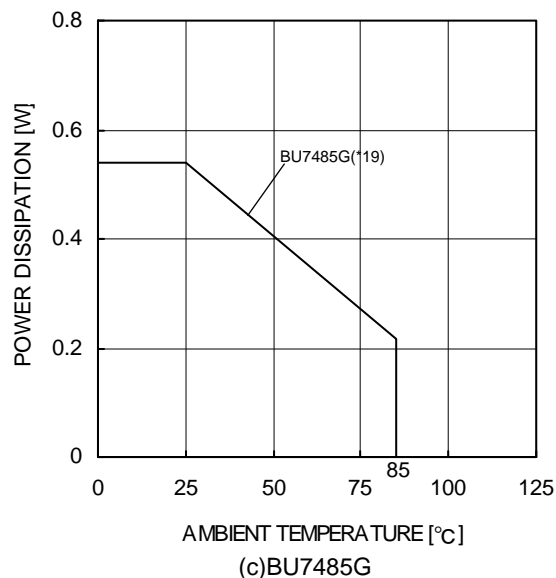
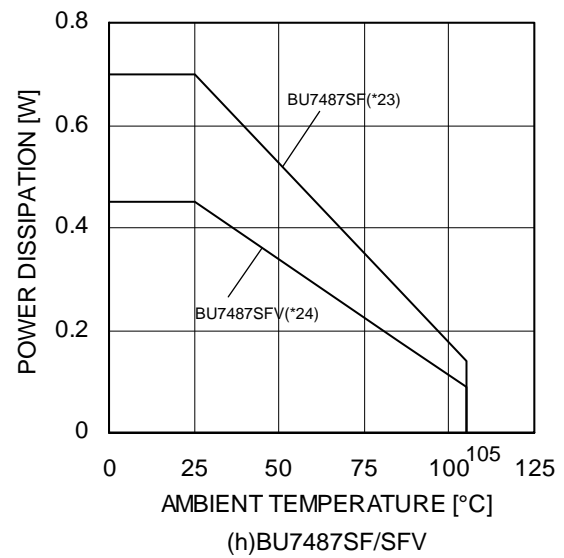
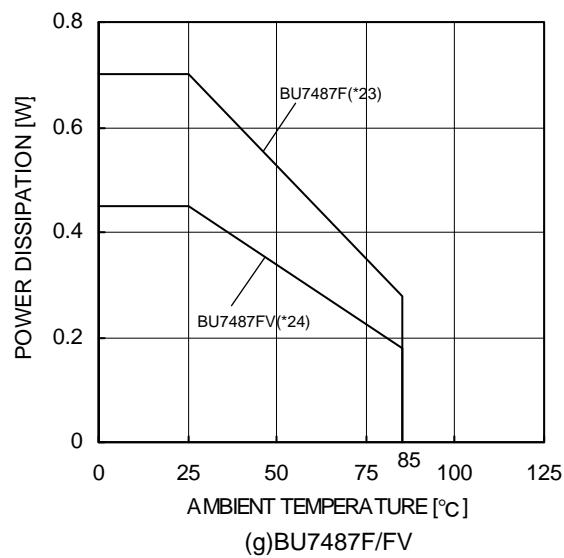
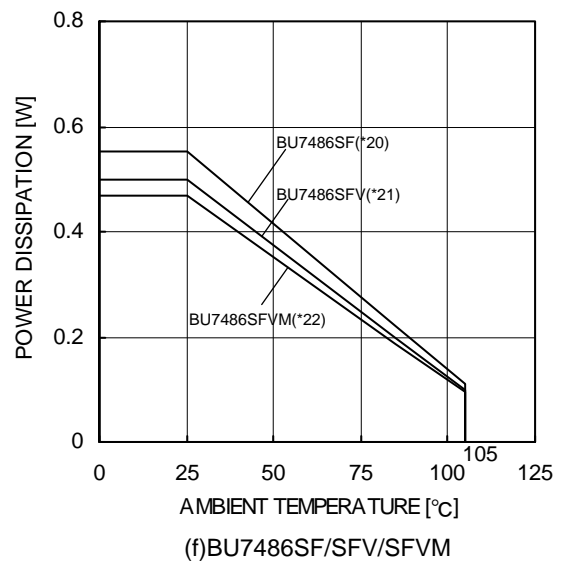
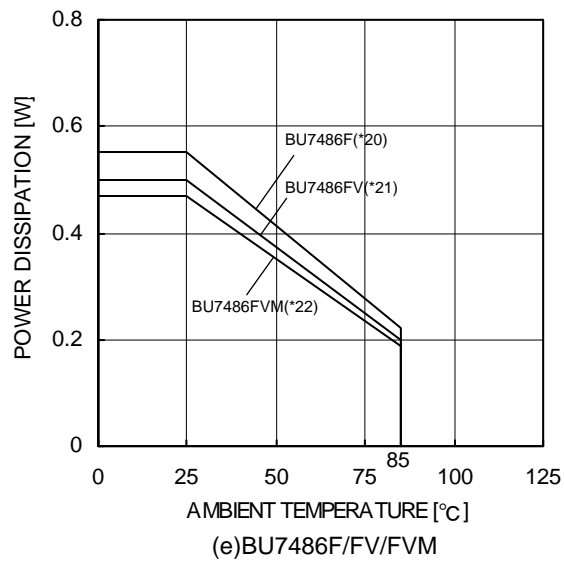


Figure 78. Thermal resistance and Derating Curve





(*19)	(*20)	(*21)	(*22)	(*23)	(*24)	Unit
5.4	5.5	5.0	4.7	7.0	4.5	mW/°C

When using the unit above Ta=25°C, subtract the value above per degree °C. Power dissipation is the value when FR4 glass epoxy board 70mm × 70mm × 1.6mm (copper foil area below 3%) is mounted.

Figure 79. Derating Curve

## Operational Notes

- 1) Unused circuits  
When there are unused circuits, it is recommended that they are connected as in Figure .56, setting the non-inverting input terminal to a potential within the in-phase input voltage range (Vicm).
- 2) Input voltage  
Applying  $VSS-0.3V$  to  $VDD+0.3V$  to the input terminal is possible without causing deterioration of the electrical characteristics or destruction, regardless of the supply voltage. However, this does not ensure normal circuit operation. Please note that the circuit operates normally only when the input voltage is within the common mode input voltage range of the electric characteristics.
- 3) Power supply (single / dual)  
The op-amp operates when the voltage supplied is between  $VDD$  and  $VSS$ . Therefore, the single supply op-amp can be used as dual supply op-amp as well.
- 4) Power Dissipation ( $P_d$ )  
Using the unit in excess of the rated power dissipation may cause deterioration in electrical characteristics including reduced current capability due to the rise of chip temperature. Therefore, please take into consideration the power dissipation ( $P_d$ ) under actual operating conditions and apply a sufficient margin in thermal design. Refer to the thermal derating curves for more information.
- 5) Short-circuit between pins and erroneous mounting  
Be careful when mounting the IC on printed circuit boards. The IC may be damaged if it is mounted in a wrong orientation or if pins are shorted together. Short circuit may be caused by conductive particles caught between the pins.
- 6) Operation in a strong electromagnetic field  
Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.
- 7) IC handling  
Applying mechanical stress to the IC by deflecting or bending the board may cause fluctuations of the electrical characteristics due to piezo resistance effects.
- 8) Board Inspection  
Connecting a capacitor to a pin with low impedance may stress the IC. Therefore, discharging the capacitor after every process is recommended. In addition, when attaching and detaching the jig during the inspection phase, make sure that the power is turned OFF before inspection and removal. Furthermore, please take measures against ESD in the assembly process as well as during transportation and storage.
- 9) Output capacitor  
If a large capacitor is connected between the output pin and  $VSS$  pin, current from the charged capacitor will flow into the output pin and may destroy the IC when the  $VCC$  pin is shorted to ground or pulled down to  $0V$ . Use a capacitor smaller than  $0.1\mu F$  between output pin and  $VSS$  pin.
- 10) Oscillation by output capacitor  
Please pay attention to the oscillation by output capacitor and in designing an application of negative feedback loop circuit with these ICs.
- 11) Latch up  
Be careful of input voltage that exceed the  $VDD$  and  $VSS$ . When CMOS device have sometimes occur latch up and protect the IC from abnormaly noise.

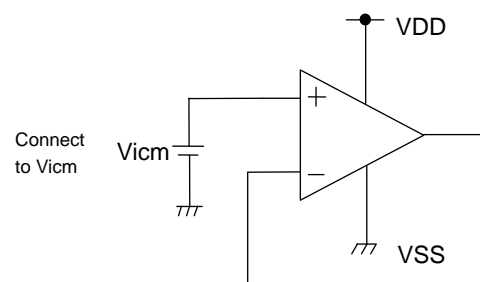
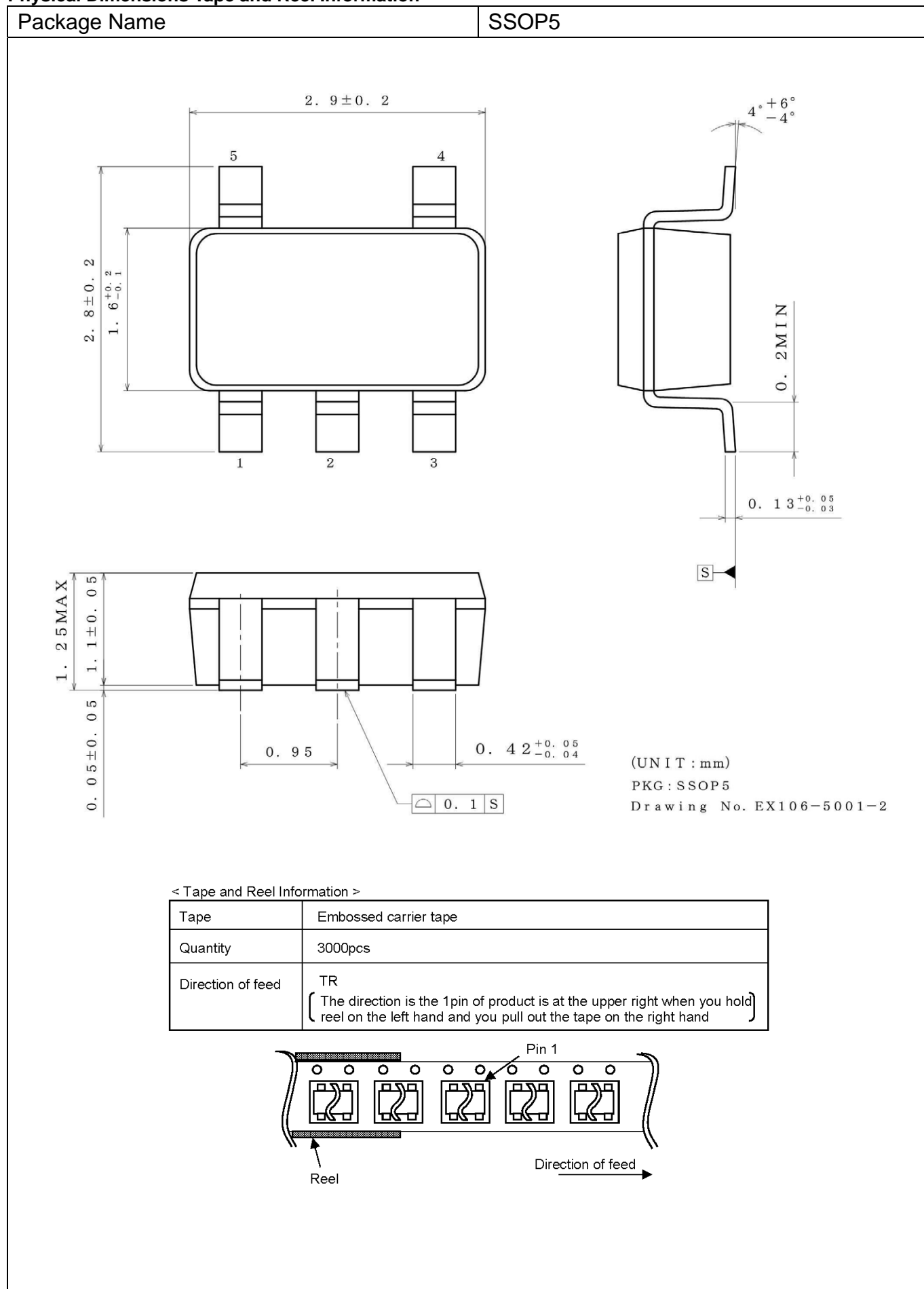
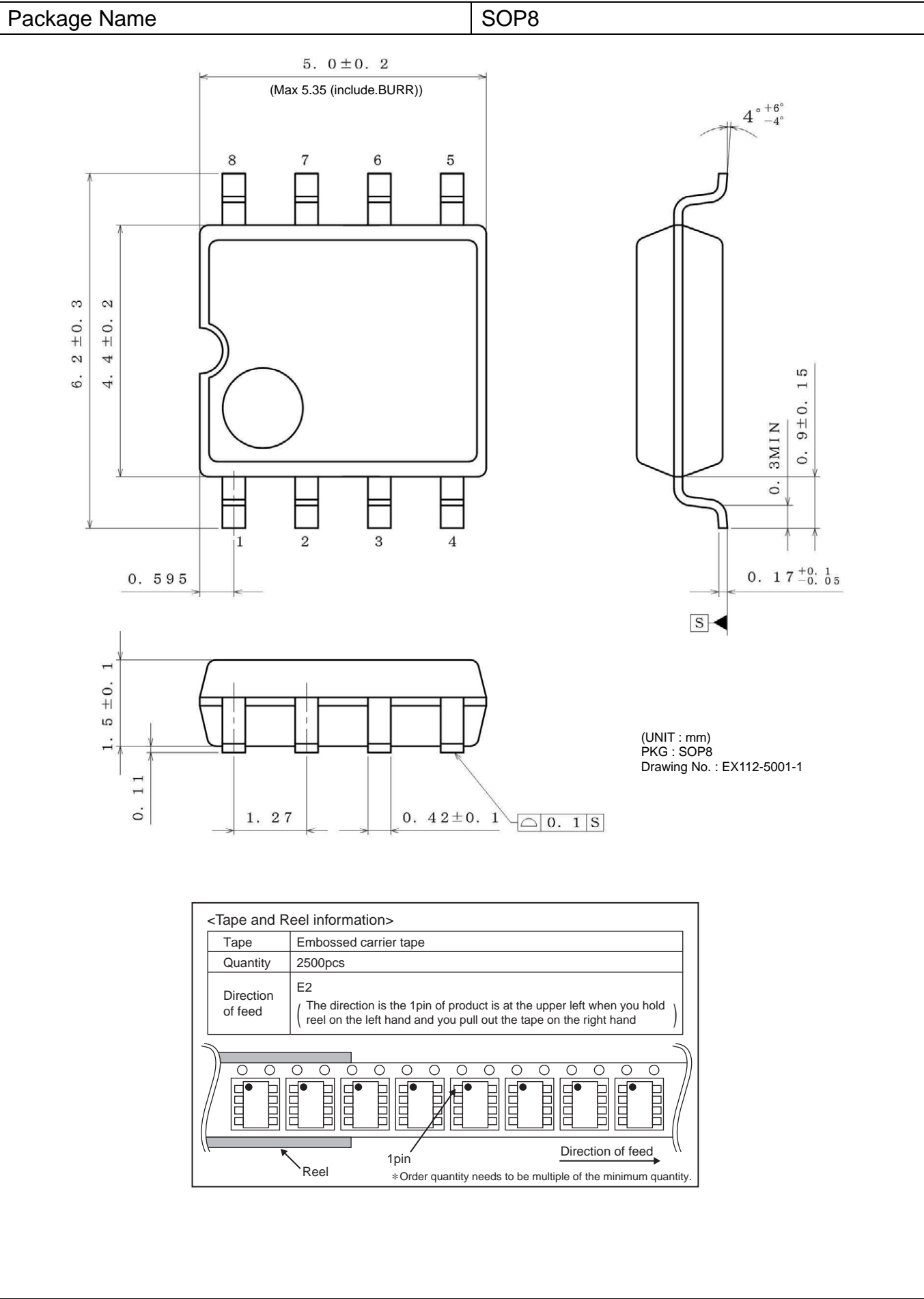


Figure 80. Example of application circuit for unused op-amp

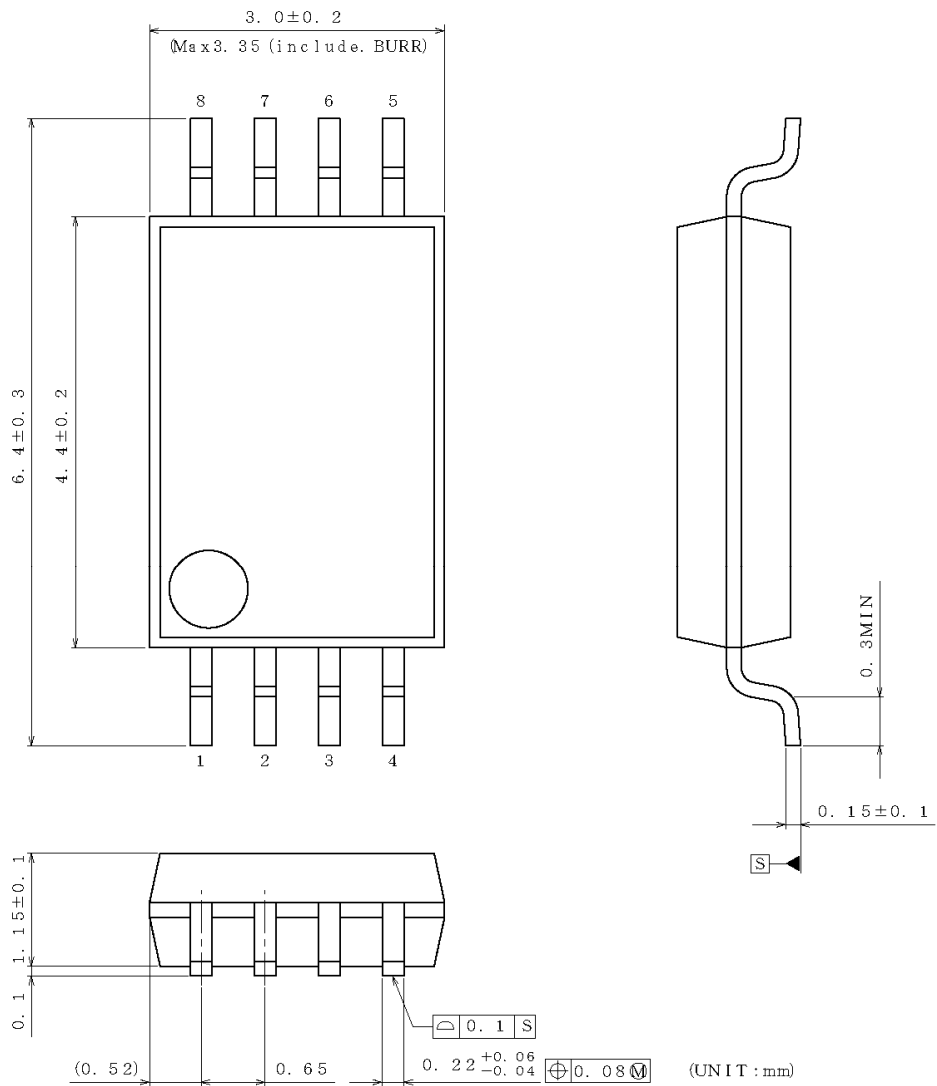
# Physical Dimensions Tape and Reel Information







Package Name	SSOP-B8
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PKG : SSOP-B8  
Drawing No. EX151-5002

<Tape and Reel information>

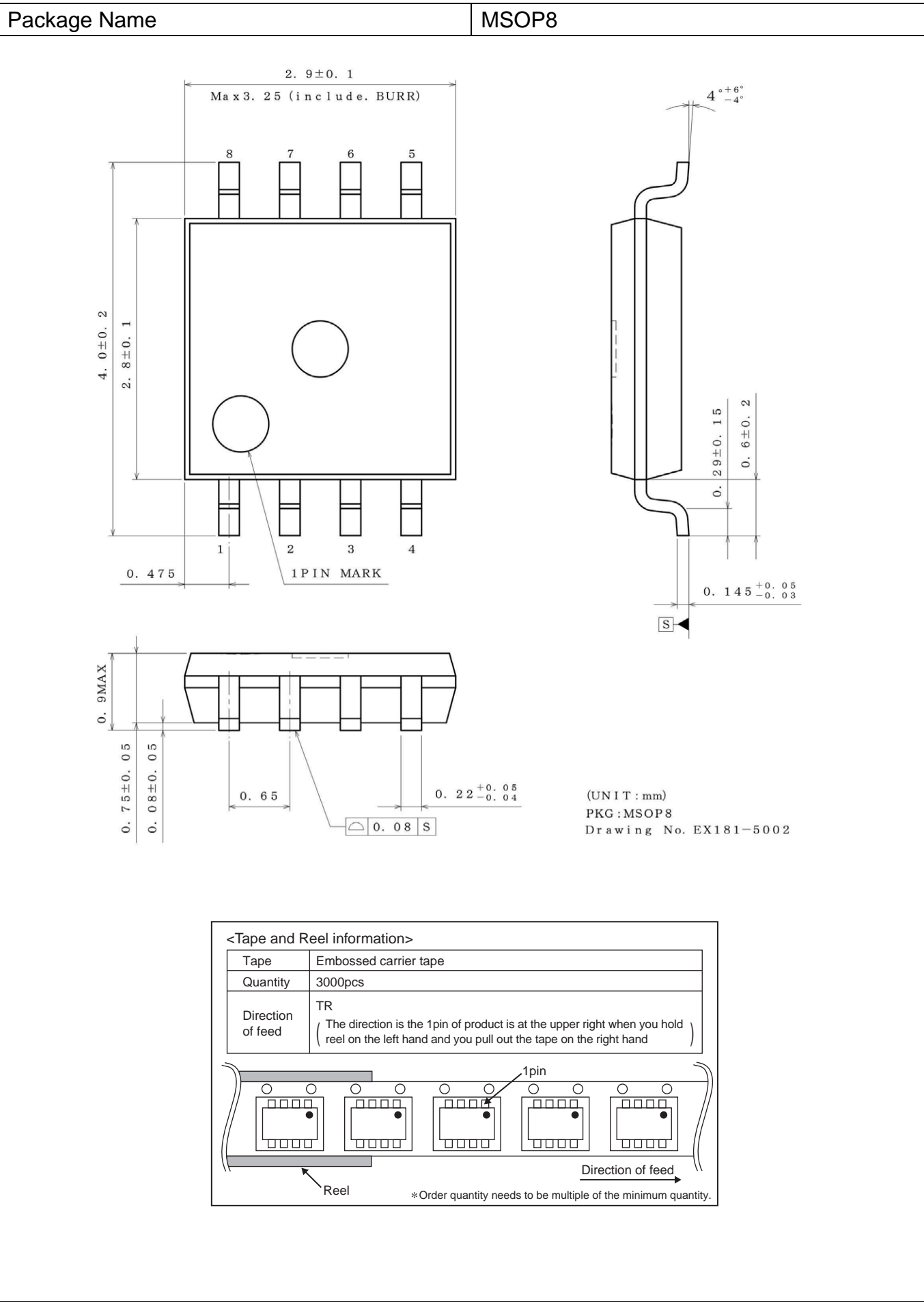
Tape	Embossed carrier tape
Quantity	2500pcs
Direction of feed	E2 (The direction is the 1pin of product is at the upper left when you hold reel on the left hand and you pull out the tape on the right hand)

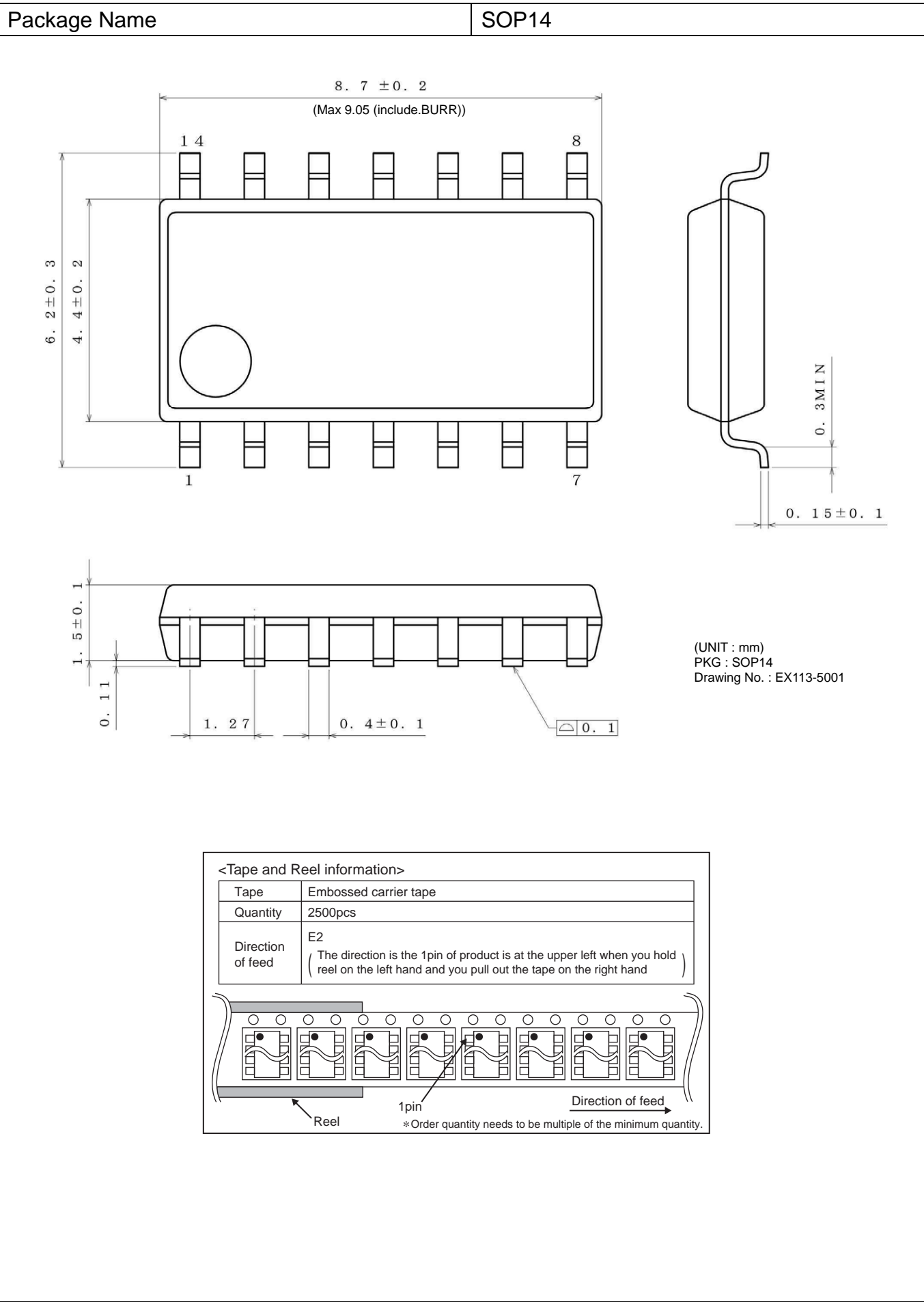
Reel

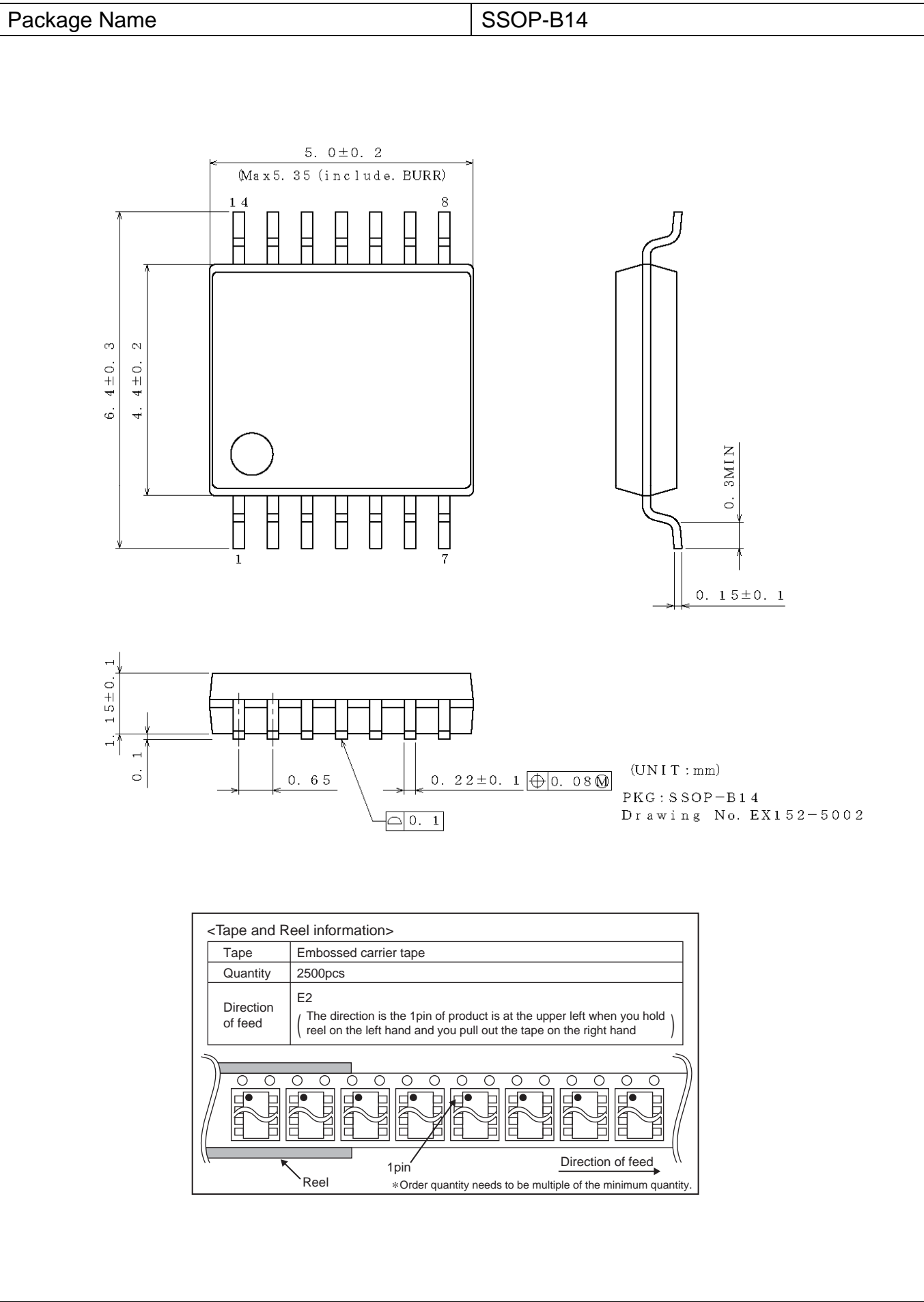
1pin

Direction of feed

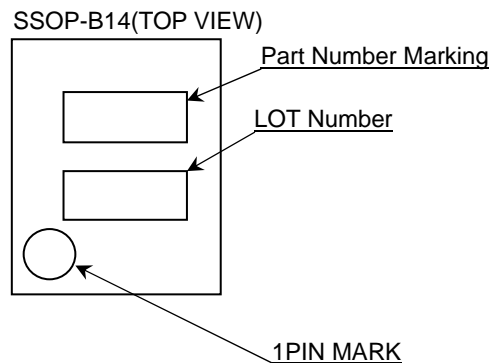
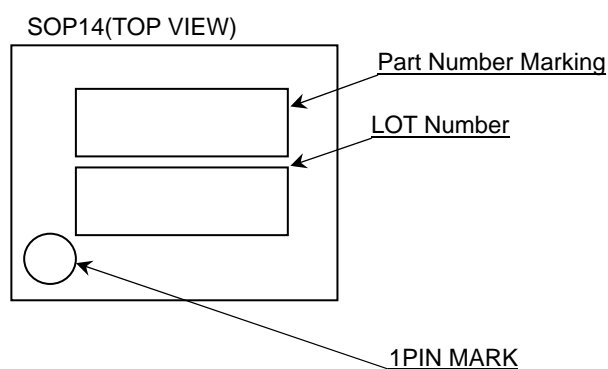
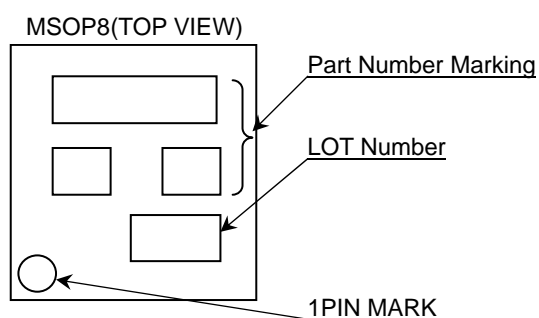
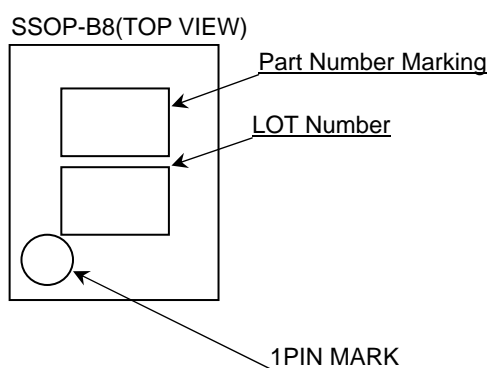
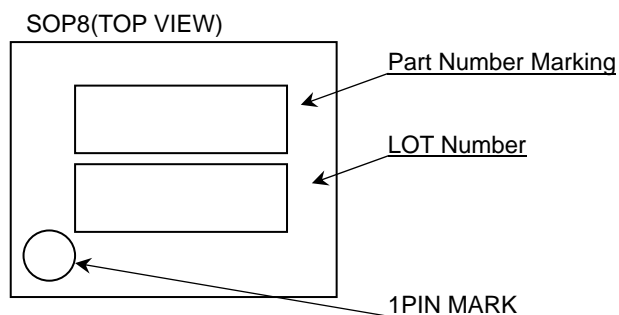
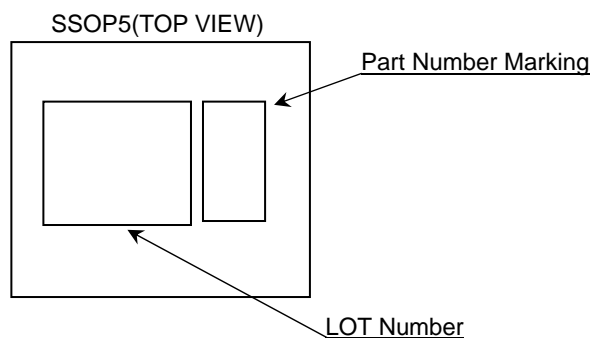
\*Order quantity needs to be multiple of the minimum quantity.







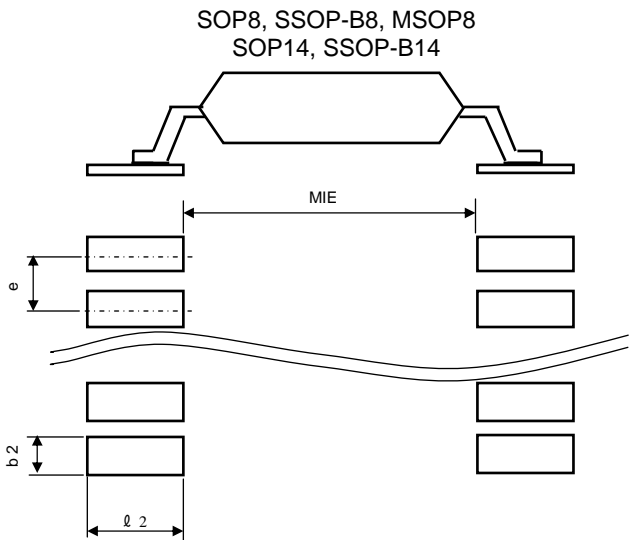
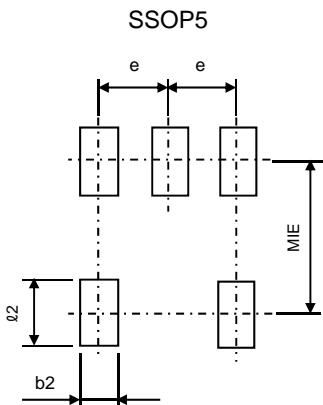
## Marking Diagram



Product Name		Package Type	Marking
BU7485	G	SSOP5	D5
BU7485S			FC
BU7486	F	SOP8	7486
	FV	SSOP-B8	
	FVM	MSOP8	
BU7486S	F	SOP8	7486S
	FV	SSOP-B8	486S
	FVM	MSOP8	7486S
BU7487	F	SOP14	BU7487F
	FV	SSOP-B14	7487
BU7487S	F	SOP14	BU7487SF
	FV	SSOP-B14	7487S

Land pattern data

PKG	Land pitch e	Land space MIE	Land length ≥ ℓ 2	Unit: mm
				Land width b2
SSOP5	0.95	2.4	1.0	0.6
SOP8 SOP14	1.27	4.60	1.10	0.76
SSOP-B8 SSOP-B14	0.65	4.60	1.20	0.35
MSOP8	0.65	2.62	0.99	0.35



Revision History

Date	Revision	Changes
12.JUL.2013	001	New Release

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  - [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure
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  - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
  - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4) The Products are not subject to radiation-proof design.
- 5) Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6) In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse) is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7) De-rate Power Dissipation (Pd) depending on Ambient temperature (Ta). When used in sealed area, confirm the actual ambient temperature.
- 8) Confirm that operation temperature is within the specified range described in the product specification.
- 9) ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.



### ●Precaution for Mounting / Circuit board design

- 1) When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2) In principle, the reflow soldering method must be used; if flow soldering method is preferred, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

### ●Precautions Regarding Application Examples and External Circuits

- 1) If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- 2) You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

### ●Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of Ionizer, friction prevention and temperature / humidity control).

### ●Precaution for Storage / Transportation

- 1) Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- 2) Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3) Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4) Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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### ●Precaution for Disposition

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- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

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**Факс:** 8 (812) 320-02-42

**Электронная почта:** [org@eplast1.ru](mailto:org@eplast1.ru)

**Адрес:** 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.